Non-Fermi-Liquid Behavior of Superconducting SnH₄

Ivan A. Troyan,¹ Dmitrii V. Semenok,^{2,*} Anna G. Ivanova,¹ Andrey V. Sadakov,³ Di Zhou,^{2,*} Alexander G. Kvashnin,⁴ Ivan A. Kruglov,^{5,6} Oleg A. Sobolevskiy,³ Marianna V. Lyubutina,¹ Dmitry S. Perekalin,⁷ Toni Helm,⁸ Stanley W. Tozer,⁹ Maxim Bykov,¹⁰ Alexander F. Goncharov,¹¹ Vladimir M. Pudalov,^{3,12} and Igor S. Lyubutin^{1,*}

Shubnikov Institute of Crystallography, Federal Scientific Research Center Crystallography and Photonics, Russian Academy of Sciences, 59 Leninsky Prospekt, Moscow 119333, Russia
 Center for High Pressure Science and Technology Advanced Research (HPSTAR), Beijing 100094, China
 P. N. Lebedev Physical Institute, Russian Academy of Sciences, Moscow 119991, Russia
 Skolkovo Institute of Science and Technology, Skolkovo Innovation Center, Bolshoi Blv. 30, Building 1, Moscow 121205,

Dukhov Research Institute of Automatics (VNIIA), Moscow 127055, Russia
 Moscow Institute of Physics and Technology, 9 Institutsky Lane, Dolgoprudny 141700, Russia
 A.N. Nesmeyanov Institute of Organoelement Compounds, Russian Academy of Sciences, 28 Vavilova str., Moscow 119334, Russia

8 Hochfeld-Magnetlabor Dresden (HLD-EMFL) and Würzburg-Dresden Cluster of Excellence, Helmholtz-Zentrum Dresden-Rossendorf (HZDR), Dresden 01328, Germany

⁹ National High Magnetic Field Laboratory, Florida State University, Tallahassee, Florida 32310, USA ¹⁰ Institute of Inorganic Chemistry, University of Cologne, Cologne 50939, Germany ¹¹ Earth and Planets Laboratory, Carnegie Institution for Science, 5241 Broad Branch Road NW, Washington, D.C. 20015, United States

¹² National Research University Higher School of Economics, Moscow 101000, Russia

Corresponding Authors: Di Zhou (di.zhou@hpstar.ac.cn), Dmitrii Semenok (dmitrii.semenok@hpstar.ac.cn), Igor S. Lyubutin (lyubutinig@mail.ru)

Abstract

We studied chemical interaction of Sn with H₂ by X-ray diffraction methods at pressures of 180-210 GPa. A previously unknown tetrahydride SnH₄ with a cubic structure (fcc) exhibiting superconducting properties below $T_C = 72$ K was obtained; the formation of a high molecular C2/m-SnH₁₄ superhydride and several lower hydrides, fcc SnH₂ and C2-Sn₁₂H₁₈, was also detected. The temperature dependence of critical current density $J_C(T)$ in SnH₄ yields the superconducting gap $2\Delta(0) = 23$ meV at 180 GPa. SnH₄ has unusual behavior in strong magnetic fields: B,T-linear dependences of magnetoresistance and the upper critical magnetic field $B_{C2}(T) \propto (T_C - T)$. The latter contradicts the Wertheimer–Helfand–Hohenberg model developed for conventional superconductors. Along with this, the temperature dependence of electrical resistance of fcc SnH₄ in non-superconducting state exhibits a deviation from what is expected for phonon-mediated scattering described by the Bloch-Grüneisen model, and is beyond the framework of the Fermi liquid theory. Such anomalies occur for many superhydrides, making them much closer to cuprates than previously believed.

Keywords: tin hydrides, superconductivity, high pressure, non-Fermi-liquid

Introduction

The study of high-temperature superconductivity is one of the most important problems in condensed matter physics. Compressed polyhydrides are promising high-temperature superconductors, which can be obtained at pressures of 1-2 Mbar. Since 2015, many remarkable hydride superconductors have been experimentally discovered. These are H₃S (with $T_C = 200 \text{ K}$) ¹, LaH₁₀ ($T_C = 250 \text{ K}$) ^{2,3}, ThH₉ ($T_C = 146 \text{ K}$) and ThH₁₀ ($T_C = 161 \text{ K}$) ⁴, YH₆ ($T_C = 226 \text{ K}$) ^{5,6} and YH₉ ($T_C = 243 \text{ K}$) ⁶, CeH₉ and CeH₁₀ ($T_C = 110$ -120 K) ⁷, CaH₆ ($T_C = 215 \text{ K}$) ^{8,9}. Most of superconducting polyhydrides contain elements of groups IIIA, IVB with d⁰-d(f)¹ valent electrons ¹⁰, whereas polyhydrides of *p*-elements, and in particular Sn, have not been studied enough.

In the last 10 years, the chemistry of polyhydrides of group IV elements (C, Si, Ge, Sn, Pb) has been intensively studied by means of the density functional theory (DFT). The experimental synthesis of such polyhydrides is carried out at high-pressure in diamond anvil cells (DACs). C, Si, and Ge hydrides are mainly low-symmetry molecular covalent compounds with moderate superconducting properties $^{11, 12, 13}$. The higher molecular silicon polyhydride SiH₄(H₂)₂ was observed in experiments of Strobel et al. and Wang et al. 14,15 . Resistive transitions with T_C up to 79 K for silicon polyhydrides were obtained under high pressure by the group of M. Eremets et al. 16 Theoretical calculations for Ge-hydrides at 200-300 GPa, predicted stable phases of GeH₃ and Ge₃H₁₁ with low symmetry, and various polymorphic modifications of the well-known GeH₄. 13,17 A new molecular compound, possibly GeH₄(H₂)₂, was obtained experimentally at 7.5 GPa. 18 According to theoretical calculations, metallic $P2_1/c$ -GeH₄(H₂)₂ is a superconductor with T_C of 76–90 K at 250 GPa. 19

The increase in metallicity of Sn to Pb results in the appearance of thermodynamically stable polyhydrides in the high-pressure phase diagram. For instance, theory predicts the formation of C2/m-SnH₁₂, C2/m-SnH₁₄ ²⁰ and various PbH₄, PbH₆, PbH₈ ²¹⁻²³ lead polyhydrides under high pressure. However, attempts to synthesize Pb polyhydrides have been unsuccessful to date ²⁴. The recent observation by Hong et al ²⁵ of a sharp drop in electrical resistance in unidentified Sn polyhydride at 71 K motivated us to investigate in detail the structure and superconducting properties of Sn polyhydrides under high pressure.

Three series of XRD experiments were carried out at different synchrotron facilities such as ESRF in 2017, PETRA in 2020 and APS in 2022. At pressures around 160-210 GPa, we observed X-ray diffraction patterns of the studied samples, which are attributed to different Sn hydrides formed. Most XRD patterns have a characteristic set of cubic $(Fm\bar{3}m)$ reflections. In the experiment performed at APS, a single-crystal XRD at a pressure of about 190 GPa was carried out. An analysis of the diffraction pattern confirmed the cubic structure $(Fm\bar{3}m)$ of the Sn sublattice in SnH₄. As we have found, tin tetrahydride is unusual superconductor, which demonstrates anomalous behavior of electrical resistance, T-linear upper critical magnetic field, and H-linear magnetoresistance in a wide range of temperatures and magnetic fields.

2. Results

2.1. High-pressure synthesis of SnH₄ with a cubic (fcc) structure

In this work, tin polyhydrides were synthesized and studied by X-ray diffraction (XRD). The previously unknown tetrahydride SnH₄ with a cubic structure (*fcc*) was synthesized at high pressures in diamond anvil cells (DACs) in two different ways. In the first approach, we used the reaction of solutions of SnCl₄ and LiAlH₄. Gaseous stannane SnH₄ was emanated, then condensed upon cooling with liquid nitrogen ²⁶. Using a cryogenic filling at a pressure of about 2.0 bar, liquefied SnH₄ was supplied through a thin capillary into the working volume of the DAC, and then compressed to high pressure at room temperature (Supporting Figure S7). Monitoring the successful loading of gaseous SnH₄ and its compression provided additional confirmation of the hydrogen content in the resulting high-pressure phase *fcc* SnH₄. In the second approach, SnH₄ was

synthesized during the interaction of pre-compressed piece of metallic Sn and hydrogen produced by laser heating of NH₃BH₃ under high pressure. A table summarizing all the performed experiments can be found in the Supporting Information, Tables S1 and S5.

Let us first consider the results of the initial experiment we performed at the ID27 beamline of ESRF in 2017 (Fig. 1). Our preliminary study of the compression of pure Sn (Fig. 1a, DAC S1) showed that at 190 GPa it exists in two modifications: hexagonal (hcp) and cubic (bcc), the latter one is dominant. In fact, the phase transition $bcc \rightarrow hcp$ starts already at 160 GPa ²⁷. However, the enthalpies of formation of these modifications differ very little (according to DFT calculations it is $\Delta H = 9.5$ meV/atom), which explains the very low rate of this transformation. As follows from the XRD pattern in Fig. 1a, at 190 GPa, the Sn unit cell volume is $V(Im\bar{3}m\text{-Sn}) = 26.9 \text{ Å}^3$, which agrees with results of a previous publication ²⁸. Interesting, but the unit cell volumes of hcp Sn and bcc Sn are very similar.

During the experiment with stannane, frozen SnH₄ was placed in DAC S2 and compressed to 180 GPa. It was found that with an increase in pressure, rapid metallization of SnH₄ occurs at around 10 GPa (Supporting Figure S9), accompanied by the disappearance of the Raman signal. At about 160 GPa, a new cubic modification of SnH₄ is formed. Figure 1b shows that the Bragg peaks of the experimental XRD patterns of SnH₄ at pressures 160-180 GPa are best indexed by a face-centered cubic lattice (*fcc*) with unit cell volume 19.6 Å³/Sn at 180 GPa. The obtained XRD patterns also contain an impurity (broadened peaks at $2\theta = 9.5^{\circ}$ and 10.2°) which can be attributed to *hcp* Sn formed during SnH₄ dissociation when loaded and compressed in the DAC S2. Stannane is thermodynamically unstable and under ambient conditions it gradually decomposes to Sn and H₂.

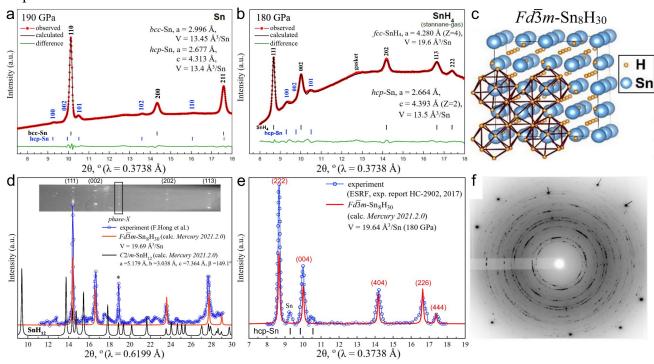


Figure 1. X-ray diffraction patterns and the Le Bail refinements of the unit cell parameters of (a) Sn at 190 GPa in DAC S1, and (b) SnH₄ and hcp Sn obtained after compression of gaseous stannane to 180 GPa in DAC S2 (ESRF-2017). (c) The crystal structure of theoretical model, $Fd\overline{3}m$ -Sn₈H₃₀, which best fits the experimental pattern. (d) XRD pattern of Sn hydride obtained by Hong et al. ²⁵ (blue curve, 206 GPa) and its fit by $Fd\overline{3}m$ -Sn₈H₃₀ model (red curve). Asterisk indicate uninterpreted reflection (phase X). Obviously, the diffraction pattern does not correspond to the C2/m-SnH₁₂ structure (black curve) proposed by Hong et al. (e) Fitting of the experimental XRD pattern after background subtraction (ESRF-2017) using theoretical model $Fd\overline{3}m$ -Sn₈H₃₀ (red curve) and hcp Sn phase (black dashes). It gives much better result than C2/m-SnH₁₂. (f) Typical diffraction pattern of fcc SnH₄ at 170 GPa (PETRA-2020, DAC D2).

Compressed Sn hydrides were also experimentally studied by Hong et al. ²⁵ The authors obtained a similar X-ray diffraction pattern (Fig. 1d), indexed as C2/m-SnH₁₂ (a = 5.179 Å, b = 3.038 Å, c = 7.364 Å, $\beta = 149.11^{\circ}$). This structure was previously predicted by DFT methods ²⁰. It can be seen that the experimental XRD clearly does not match the theoretically predicted XRD of SnH₁₂ (black curve in Fig. 1d). At the same time, the experimental XRD pattern (blue curve in Fig. 1d) fits well with the theoretical model of fcc SnH₄, namely $Fd\bar{3}m$ -Sn₈H₃₀ (= SnH_{3.75}, red curve in Fig. 1d), which is discussed in details in the Supporting Information ("Crystal structure search" section). The unit cell volume of the Sn₈H₃₀ is V = 19.64 Å³/Sn (or 628.68 Å³ for Z = 32) at 180 GPa. Using the data obtained in the ESRF-2017 experiment, we refined unit cell parameters of $Fd\bar{3}m$ -Sn₈H₃₀, which were found to be in a good agreement with the results of calculations (Supporting Tables S5, S8).

2.2. Synthesis of molecular SnH₁₄

The next experiments were performed at the P02.2 PETRA III beamline in 2020. As has already been shown, stannane compression leads to formation of mixtures of *hcp* Sn and cubic SnH₄. This indicates an insufficient amount of hydrogen for the complete conversion of Sn to polyhydrides. Therefore, to obtain tin hydrides with a higher hydrogen content (similar to SrH₂₂ ³³ and BaH₁₂ ³⁴), we decided to use ammonia borane NH₃BH₃ (AB) as source of H₂ in DACs D2 and M2.

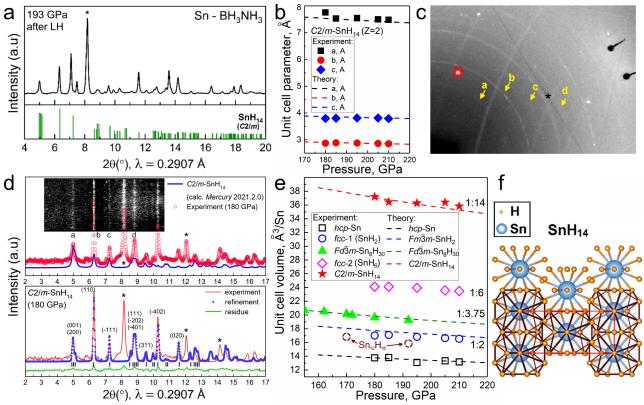


Figure 2. X-ray diffraction patterns and the Le Bail refinements of the unit cell parameters of Sn hydrides in DACs D2 and M2. (a) XRD pattern of Sn in NH₃BH₃ media after the laser heating (LH) at 193 GPa. Predicted XRD of C2/m-SnH₁₄ are shown on the bottom panel. (b) Experimental and theoretical dependences of the unit cell parameters on the pressure for C2/m-SnH₁₄. (c) Typical diffraction pattern at 180 GPa (PETRA-2020, $\lambda = 0.2904$ Å). Asterisks denote uninterpreted peaks, "a-d" denote main reflections from SnH₁₄. (d) Comparison of experimental and calculated XRD reflection intensities for SnH₁₄ ("a-d"). Inset: diffraction image ("cake"). Bottom panel: the Le Bail refinement of C2/m-SnH₁₄. Unidentified reflections are marked by asterisks. The experimental data, fitted line, and residues are shown in red, blue, and green, respectively. (e) Pressure—unit cell parameters diagram for all tin hydrides synthesized in our experiments: stars, rhombuses, triangles, circles and squares show the experimental data, lines depict the theoretical calculations. (f) Crystal structure of SnH₁₄ polyhydride.

The use of AB has yielded interesting results. We found that in addition to SnH₄, several new compounds are formed, whose XRD patterns mostly correspond to the higher molecular polyhydride C2/m-SnH₁₄ predicted in 2016 ²⁹ (Fig. 2). The refinements of the unit cell parameters of synthesized SnH₁₄ (Figs. 2a, b, d) are in a good agreement with the theoretical DFT calculations (Supporting Table S9).

This polyhydride has an orthorhombic *Immm*-Sn sublattice and a hydrogen sublattice, consisting of H₂ ($d_{\rm HH} = 0.833$ Å) and H₃ ($d_{\rm HH} = 0.92$ Å) fragments. According to molecular dynamics modeling, C2/m-SnH₁₄ is dynamically stable in the anharmonic approximation (Supporting Figure S13). Moreover, SnH₁₄ exhibits the properties of a typical metal with a high density of electronic states at the Fermi level (DOS). The DOS projection on hydrogen atoms, $N_F(H) = 0.32$ states/eV/f.u., is larger than that on Sn atoms ($N_F(Sn) = 0.23$ states/eV/f.u.). The hydrogen sublattice exhibits anisotropic properties, and is in a solid (not glassy, like in P1-SrH₂₂ 30) state. Due to the presence of large amount of molecular hydrogen in the structure of SnH₁₄, its Debye temperature is rather high ($\theta_D \sim 1500$ K, ω_{log} up to 1252 K). Also, the superconducting properties are well pronounced, the electron-phonon coupling (EPC) coefficient is $\lambda = 1.25$, and the critical temperature is $T_C = 107$ –133 K at 200 GPa ($\mu^* = 0.15$ -0.1) in the harmonic approximation (Supporting Figures S12-S13). This significantly distinguishes molecular tin polyhydrides from similar compounds of barium (BaH₁₂, which is a low- T_C superconductor, $T_C \sim 20$ K) and strontium (SrH₂₂, which is a semiconductor).

In our last experiment performed in 2022 at APS, Sn and AB were again used. The studies were carried in DAC S3 with a wide opening angle (\sim 70°) and diamond anvils of the Böhler-Almax type to obtain a single-crystal XRD pattern (Supporting Figure S2), where one phase was indexed by the *fcc* SnH₄ (*R*-factor is 4.75 %). A co-product of the synthesis is a lower hydride, whose X-ray diffraction pattern can be indexed by C2-Sn₁₂H₁₈ (= Sn₂H₃, R_1 = 5.83%, Supporting Figure S4) with an experimental unit cell volume of 15.85 Å³/Sn at 192 GPa. This phase was found during the USPEX crystal structure search. Obtained Sn₁₂H₁₈ consists of [SnH₄] structural blocks with $d_{\text{Sn-H}}$ = 1.87-1.97 Å (at 200 GPa) and multiple Sn-H-Sn hydrogen bonds.

Summarizing the structural studies of tin hydrides at high pressures, we can conclude that the Sn-H system is rich in various compounds. Structural interpretation of most of these compounds is difficult because of the low enthalpy of formation of Sn hydrides, which does not allow reliable use of computational methods to predict thermodynamically stable phases. Obviously, the main product of the reaction of tin with hydrogen is fcc SnH₄ (V = 19.6 Å³/Sn at 180 GPa). Among the higher polyhydrides C2/m-SnH₁₄ (V = 35.8 Å³/Sn at 193 GPa) and, possibly, fcc SnH_{6±x} (V = 24.1 Å³/Sn at 180 GPa, x = 0.5) were found. Among the lower hydrides fcc SnH_{2+x} (V = 17.0 Å³/Sn at 185 GPa, x = 0.5) and C2-Sn₁₂H₁₈ (V = 15.85 Å³/Sn at 192 GPa) were synthesized.

2.3. Transport properties of fcc SnH₄

Knowing the crystal structure of new hydride compounds, it is very important to experimentally study their physical properties. Therefore, we studied the transport properties of the obtained fcc SnH₄ using a four-electrode Van der Pauw circuit sputtered on diamond anvils. At 180 GPa, a sharp drop in the sample resistance (by a factor of 10^3) at $T_C = 72$ K with the width of $\Delta T_C = 2$ K was revealed (Figure 3a). It has been established that in external magnetic fields up to 16 T the value of the critical temperature T_C decreases almost linearly, which is typical for superconductors (Figure 3b, c). In the external magnetic fields (H_{ext}) we observed significant broadening of superconducting transitions in the range of 2 - 10 K (Fig. 3d), which correlates with data of Ref. ²⁵. According to previously known data ³¹⁻³³, the superconducting transitions of some polyhydrides practically do not broaden in relatively weak magnetic fields ($\mu_0 H_{ext} < 0.5 B_{C2}(0)$). Here, due to much lower critical field for SnH₄ we were able to trace the $H_{C2}(T)$ dependence over almost the entire temperature range. As Figures 3b,d show, SnH₄ manifests pronounced broadening of the superconducting transition in external fields.

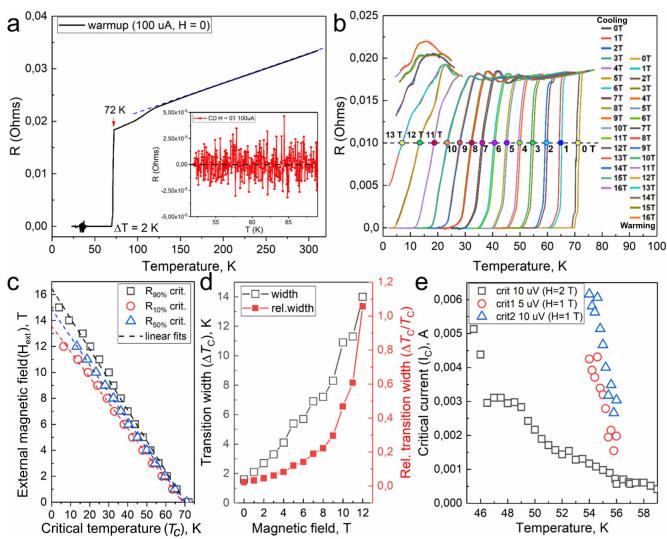


Figure 3. Electric transport properties of fcc SnH₄ at 180 GPa studied in magnetic fields. (a) Temperature dependence of the electrical resistance of the sample. Fully linear R(T) is observed from 300 K to 120 K. At about 30 K, the electrode system becomes unstable. Inset: residual resistance at $T < T_C$. (b) Displacement of the superconducting transition in external magnetic fields up to 16 T. WA - heating cycle, CD - cooling cycle. (c) Experimental temperature dependence of $T_C(H_{\text{ext}})$. Using linear interpolation by different criteria (90, 50 and 10% of the normal state resistance) the values of upper critical magnetic field (B_{C2}) were obtained. (d) Relative and absolute broadening of superconducting transitions in external magnetic fields. (e) Temperature dependence of the critical current of the Sn hydride sample in external magnetic fields of 1 and 2 T.

Linear extrapolation of $B_{C2}(T)$ to $T_C = 0$ K allows the upper critical magnetic field of SnH₄ to be estimated as $B_{C2}(0) = 14$ -16 T. This is a very low value compared to other hydride superconductors. For example, YH₆ ⁵ has the $B_{C2}(0)$ value of at least 110-160 T, and for LaH₁₀ ² it is at least 140-160 T.

From measurements of the temperature dependence of resistance, we focus firstly on a pronounced feature (kink) around 120 K (Fig. 3a, Supporting Figures S17b, S18b) which we observed in several experiments. Hong et al. ²⁵ also saw a similar kink in the R(T) dependence for SnH₄. Such anomalous behavior of R(T) was previously revealed in many hydrides, for instance, in BaH₁₂ ³⁴, H₃S ¹ and LaH₁₀ ^{2,35}. Additional examples are given in Supporting Figures S20-S21. Secondly, resistance is completely linearly dependent on temperature ($\beta = R_0^{-1} dR/dT = 1.77 \times 10^{-3} \text{ K}^{-1}$) in the range from 120 to 320 K (see Fig.3a). Because of these two anomalies, the resistance of SnH₄ in the normal (non-superconductive) state can hardly be fitted with the Bloch-Grüneisen model ³⁶ of phonon-mediated scattering. Indeed, an attempt to use the Bloch-Grüneisen fit ³⁶ leads to a very low Debye temperature (θ_D) of about 100 K, which is not typical for polyhydrides under high pressure.

The linear dependence of the upper critical field on temperature requires even more detailed discussion. For superconductors described by the Bardeen-Cooper-Schrieffer (BCS) theory ³⁷, the generally accepted model for the $B_{C2}(T)$ dependence is the Werthamer-Helfand-Hohenberg (WHH) model, which predicts flattening of the $B_{C2}(T)$ dependence at low temperatures ³⁸. However, for many compressed polyhydrides (e.g., YH₄, LaH₁₀ at low pressure 39) the $B_{C2}(T)$ function is almost linear down to temperatures of 1-2 K. This behavior may be explained by the presence of two superconducting gaps ⁴⁰⁻⁴³ (Supporting Figure S19). Indeed, for a number of polyhydrides (Fm3m-LaH₁₀, Fm3m-YH₁₀, P6₃/mmc-YH₉) the solution of the anisotropic Migdal-Eliashberg equations indicates the presence of two superconducting gaps 44-46. However, this explanation is unsatisfactory, since two-gaps superconductivity is not universal in hydrides (e.g., Im3m-CaH₆ ⁴⁷). The $B_{\rm C2}({\rm T})$ dependences of hydrides have no ascending segments, and polyhydrides that behave in full compliance with the WHH model are currently unknown. Another explanation is related to the mesoscopic inhomogeneity of the sample, the presence of regions with different composition and hydrogen content and, consequently, with different T_C and B_{C2} ^{32,48,49}. As long as "islands" of superconductivity are still bound via the Josephson effect, one can still detect the superconductivity of the sample. The proposed explanation agrees with the appearance of an ascending feature in R(T), indicating a significant increase in resistance at low temperatures (Fig. 3b), possibly, due to the complex and shunted trajectory of the electric current.

One of the distinguishing features of superconductors is the existence of a self-field critical current density $J_{\rm C}(T)$, when superconductivity gets destroyed and the electrical resistance of the material becomes nonzero. The low upper critical magnetic field, as expected, leads to low values of the critical current of the sample: $I_{\rm C}=6$ mA at 55 K in a magnetic field of 1 T, that corresponds to $J_{\rm C}(0)\sim 200$ A/mm² for the sample with 1 µm thickness and 30 µm diameter (Fig. 3e, Supporting Figure S17a). The critical current measurements can be used to estimate the superconducting gap in SnH₄. Talantsev et al. ⁵⁰ proposed the following model for s-wave superconductors

$$J_c(T) = \frac{B_{c1}(T)}{\mu_0 \lambda(T)},$$
 (1)

where $\lambda(T)$ is the penetration depth, and $B_{C1}(T)$ – is the lower critical magnetic field. Detailed equations for this model are provided in Supporting Information, eq. S5. Surprisingly, superconductivity in tin hydride is quite easily suppressed by electric current. Fit of experimental $J_C(T)$ data (Supporting Figure S17) yields $2\Delta(0) \approx 23$ meV and $2\Delta(0)/k_BT_C = 3.83$, in a reasonable agreement with the BCS value of 3.52. At the same time, according to the Talantsev-Tallon model, the self-field critical current density in SnH₄ at 0 K can reach $J_C(0) = 3.1$ kA/mm².

The results of studying the magnetoresistance (MR) of SnH₄ at 180 GPa in pulsed magnetic fields up to 65 T revealed a curious result. The dependence of the electrical resistance $\delta R \propto \mu^2 B^2$ on magnetic field B_{ext} (where μ is the mobility of carriers) ⁵¹ is quadratic only in relatively weak magnetic fields. Then, rather quickly (when $B_{ext} > B_{crit}$) this dependence becomes linear $\delta R \propto (B - B_0)$, see Figs. 4a, c. Taken separately, each of the two effects – linear $\delta R(T)$ and linear $\delta R(B)$ dependences may find analogies in other fields of physics. For example, linear $\delta R(T)$ occurs in strongly interacting two-dimensional systems of electrons ⁵² where it originates from interaction assisted impurity scattering. Linear R(B) is known for polycrystalline samples (Kapitza linear magnetoresistance) and originates from scattering by the grain boundaries in quantizing magnetic fields ⁵³⁻⁵⁵, or is found in materials with Dirac cone spectrum. However, the combination of the two effects in one and the same material leaves the most probable only one analogy – with high- T_C cuprates which exhibit non-Fermi-liquid behavior in the normal state ^{56,57}. These so called strange metals are known to be materials between insulators and metals⁵⁸. Following the interpretation widely used for cuprate superconductors, we can say that the combination of the anomalous T and B-linear behavior of electrical resistance and magnetoresistance, as well as the upper critical field of fcc SnH₄ allows to characterize the tin tetrahydride in the normal state as a non-Fermi-liquid strange metal.

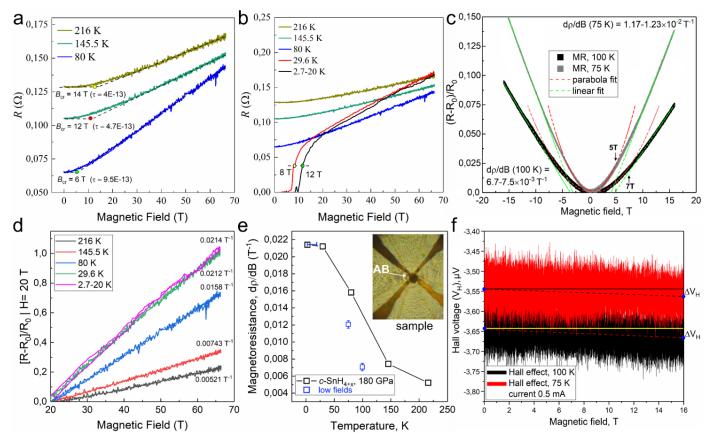


Figure 4. Magnetoresistance (MR) of the fcc SnH₄ at 180 GPa measured in pulse magnetic fields. (a) Dependence of the electrical resistance on the applied magnetic field at temperatures $T > T_C$. A pronounced transition from a quadratic to a linear $R(H_{ext})$ dependence is observed. (b) Dependence of the sample resistance on the applied magnetic field over the entire temperature range. Due to the heating by eddy currents during the pulse, the sample temperature of 2.7 K cannot be considered reliably fixed. (c) MR in low magnetic fields up to 16 T at temperatures 75 and 100 K. (d) Linear part of the relative MR calculated for all temperature points starting from a field B_{ext} of 20 T. (e) Dependence of linear MR on temperature. (f) Attempt to measure the Hall effect in Sn hydrides at temperatures 75 and 100 K.

In general, the results of experiments in pulse magnetic fields agree with measurements in steady fields below 16 T: the MR of SnH₄ only in the initial part (up to 5-7 T) is a quadratic function of the field. With a further increase in the field, MR becomes completely T-linear. In addition, measurements in weak magnetic fields (0-16 T, at 75-100 K, Figs. 4c,f) allowed us only to estimate the Hall coefficient $R_{\rm H} \sim 5 \times 10^{-12}$ m³/C. The Hall voltage was $\Delta V_{\rm H} \sim 1-2 \times 10^{-8}$ V at a current of 0.5 mA. It is impossible to give a more accurate estimate, since we do not know the exact thickness (t) of the sample (t ~ 1-2 µm). Nevertheless, this value of $R_{\rm H}$ is rather small which allows us to consider the concentration of charge carriers in SnH₄ under pressure to be 10^{29} - 10^{30} m⁻³ (within $R_{\rm H} = 1/n_{\rm e}$ e, the sign of the carrier charge is unknown). Alternatively, the low Hall coefficient may be due to high hole mobility, which is quite unusual for superhydrides under pressure.

Given the almost identical value of the Fermi velocity $V_F = 2.5 \times 10^5$ m/s in various hydride superconductors ⁵⁹, we can estimate the mean free path of an electron in SnH₄ in terms of the Drude theory ^{60,61}.

$$l_e = V_F \tau = \frac{m_e R_H}{eRt},\tag{2}$$

where R is electrical resistance of the sample. It can be seen that in the SnH₄ the mean free path of electrons $l_e \cong 10^{-15} V_F = 3.5$ Å, which is comparable to the size of unit cell. Of course, this is a very small value corresponded to extremely "dirty" and disordered compounds. In a previous study of (La, Nd)H₁₀ ³² we found that the electron mean free path is also very short (~1.3 nm) and compatible with the unit cell parameter. This may lead to quantum effects of weak localization ⁶² even in three-dimensional samples of SnH₄, since the corresponding correction ($\delta\sigma$) to the electrical conductivity (σ) may be significant (eq. 3).

$$\frac{\delta\sigma}{\sigma} = -\frac{1}{k_F^2 l_e} \left(\frac{1}{l_e} - \frac{1}{L_{\omega}} \right) \cong -1. \tag{3}$$

Weak localization effects are well known for semiconductors and graphene 63 , in particular, they are responsible for the appearance of negative magnetoresistance in thin films of Si, Ge and Te 64 . A similar phenomenon was recently observed for (La,Nd)H₁₀, which also exhibits a negative magnetoresistance in the range of 200–250 K 32 . The weak localization can also lead to an unusual R(T) dependence and sign reversal of dR/dT 65 , as it was observed for lanthanum-cerium (La,Ce)H₉ and sulfur H₃S hydrides (Supporting Figures S21c-22c).

3. Discussion

Let us first discuss selection of the best theoretical structural model for fcc SnH₄ in terms of the experimental superconducting properties. The two predicted structures, namely $R\bar{3}m$ -Sn₁₂H₄₅ and $Fd\bar{3}m$ -Sn₈H₃₀, are dynamically stable, well describe the experimental powder XRD patterns, and lie near the convex hull of Sn-H system (Supporting Figure S1). They both have electronic band structures (Supporting Figure S11) typical of metals. The low density of electronic states at the Fermi level (≈ 0.5 states/eV/Sn) also has a relatively weak contribution from the hydrogen atoms (half the contribution of Sn), which is usually attributed to low critical temperature of superconductivity 66,67 . The calculated critical temperature of superconductivity for $Fd\bar{3}m$ modification ($T_{\rm C}=73$ -91 K, Supporting Figure S22) is close to the experimental one (72-74 K) observed in fcc SnH₄ at 180 GPa. The results of single-crystal XRD, which do not reveal any deviations from the ideal fcc structure, as well as high critical temperature of superconductivity, indicate that only $Fd\bar{3}m$ -Sn₈H₃₀ theoretical model agrees well with the experimental data for fcc SnH₄ at 180 GPa.

It is now believed ¹ that hydrides belong to the conventional BCS superconductors and their behavior in the normal state can be described in terms of the Fermi liquid model, widely used for metals. However, gradually accumulating experimental data cast doubt on this point of view. First of all, it is necessary to note the change in the sign of the temperature coefficient of electrical resistance (dR/dT) from positive to negative along with decreasing pressure in DACs. This was observed in superconducting H₃S ¹ and lanthanum-cerium polyhydrides ⁶⁸ (Supporting Figure S20). The decrease in electrical resistance with increasing temperature is unusual for metals, but is a distinctive feature of insulators. Moreover, a similar behavior was recently observed in a cuprate superconductor Bi-2212 (Bi₂Sr₂CaCu₂O₈₊), studied at high pressures ⁶⁹. This experiment demonstrated that pressure (*P*) may play the same role as the degree of doping (x) ^{70,71}, separating the superconducting phase from the pseudo-gap phase with an insulating-like negative dR/dT.

As many cuprates have a dome-shaped dependence of the critical $T_C(x)$ on the degree of doping (x), so do most superhydrides have a similar $T_C(P)$ dependence with a sharp decrease in T_C with pressure decreasing 1,2,6,7. Such decompression is usually accompanied by a sharp increase in the EPC parameter λ to the maximum within the Migdal-Eliashberg theory 72,73 values of 3-3.7 followed by decomposition of a compound. There is such a strong electron-phonon interaction that even a small shift of atoms causes a large change in the electronic structure, turning the metal into an insulator with local separation of charges (as in ferroelectrics) and formation of polarons 75 . What can happen to the atomic sublattice of hydrogen in superhydrides under these conditions? It would be logical to assume that hydrogen atoms will form more stable H_2 molecules, and the compound will begin to exhibit the properties of a semiconductor, which is typical for molecular hydrides. That is exactly the boundary between the superconducting and pseudo-gap phases in polyhydrides.

The behavioral peculiarities of the electrical resistance of superhydrides have not received much attention since discovery of H_3S , but many of them (e.g., Supporting Figures S20-S21) show R(T) typical of strange metals in one pressure range, and the usual behavior of a Fermi liquid in another one. Our observation

that the studied SnH₄ changes from metal to insulator as pressure or magnetic field changes clearly points that this material is in the proximity to a quantum critical point. Amazingly, but polyhydrides may turn out to be much closer to cuprate superconductors than previously thought, as Talantsev et al. ⁷⁶⁻⁷⁹ predicted based on an analysis of the T_C/T_F ratio (T_F is the Fermi temperature).

4. Conclusions

We have synthesized a series of novel tin hydrides at pressure of 180-210 GPa: C2/m-SnH₁₄, fcc SnH₄, fcc SnH_{6+x}, fcc SnH₂ and C2-Sn₁₂H₁₈. The main product of the reaction of Sn with hydrogen at these pressures is the cubic (fcc) superconducting tetrahydride SnH₄, with the composition being confirmed by XRD analysis performed after compression of cryogenically loaded stannane. The critical superconducting temperature of this compound is $T_C = 72$ K at 180 GPa, the upper critical field is $B_{C2}(0) = 14$ -16 T, the self-field critical current density is $J_C(0) \sim 3.1$ kA/mm², and the superconducting gap $2\Delta(0)$ is 23 meV. SnH₄ contains covalent Sn-H bonds, has soft modes in phonon spectra and the large electron-phonon coupling parameter $\lambda \approx 2.5$ due to important contribution of anharmonicity to the crystal lattice dynamics.

Another discovered polyhydride C2/m-SnH₁₄ with ultra-high hydrogen content, belongs to the same family of compounds as BaH₁₂ ³⁴, LaH₁₁₋₁₂ ⁸⁰, SrH₂₂ ³⁰, and confirms the existence and prevalence of such a type of high molecular polyhydrides. Unlike other members of this group, SnH₁₄ is expected to be a high-temperature superconductor with $T_C = 93 - 112$ K.

Tin tetrahydride (SnH₄) exhibits a reproducible anomalous linear dependence of electrical resistance on temperature, T-linear dependence of the upper critical field, and a H-linear dependence of magnetoresistance over a wide range of magnetic fields and temperatures. Such a non-Fermi-liquid behavior is reminiscent to the unconventional normal state of cuprate high-temperature superconductors.

Supporting Information

Supporting Information is available from the authors.

Author contributions

I.A.T., D.V.S., and A.G.I. contributed equally to this work. I.A.T, D.V.S., D.Z., T.H. and S.W.T. performed the experiments. I.A.K. performed the T-USPEX and anharmonic phonon density of states calculations. A.G.K., D.V.S. and D.Z. prepared the theoretical analysis and calculated the equation of states, electron and phonon band structures, and superconducting properties of tin hydrides. D.V.S. and D.Z. analyzed and interpreted the experimental results and wrote the manuscript. I.A.T., A.V.S., and O.A.S. made the electric transport measurements in low magnetic fields. M.V.L. analyzed Raman experiments and edited the manuscript. D.S.P. built a system for the synthesis and cryogenic loading of stannane. T.H. and S.W.T. carried out the measurements in pulsed magnetic fields at HZDR HLD. I.S.L. and V.M.P. directed the research, analyzed the results and edited the manuscript. All the authors provided critical feedback and helped shape the research.

Acknowledgements

In situ X-ray diffraction experiments at high pressure were performed on ESRF, stations ID 18 and ID 27, Grenoble, France (proposal No. HC-2902, 2017), as well as on PETRA III, beamline P02.2, Hamburg, Germany (2020), and at HPCAT (sector 16) of the APS, Argonne National Laboratory. HPCAT operations are supported by U.S. Department of Energy (DOE) National Nuclear Security Administration's Office of Experimental Sciences. The APS is a DOE Office of Science User Facility operated for the DOE Office of

Science by Argonne National Laboratory under Contract No. DE-AC02-06CH11357. Experiments in pulsed magnetic fields were done in Dresden High Magnetic Field Laboratory (HLD HZDR), Dresden, Germany (2021). This work was supported by HLD-HZDR, member of the European Magnetic Field Laboratory (EMFL). The high-pressure experiments were supported by the Ministry of Science and Higher Education of the Russian Federation within the state assignment of the FSRC Crystallography and Photonics of the RAS and by the Russian Science Foundation (Project No. 22-12-00163). I.A.K. thanks the Russian Science Foundation (grant No. 21-73-10261) for the financial support of the anharmonic phonon density of states calculations and molecular dynamics simulations. SEM, XRF, and XRD studies of the initial alloys were performed using the equipment of the Shared Research Center FSRC Crystallography and Photonics of the RAS. I.A.T. and A.G.I. acknowledge the use of the facilities of the Center for Collective Use "Accelerator Center for Neutron Research of the Structure of Substance and Nuclear Medicine" of the INR RAS for highpressure cell preparation. The research used resources of the LPI Shared Facility Center. V.M.P, A.V.S. and O.A.S. acknowledge the support of the state assignment of the Ministry of Science and Higher Education of the Russian Federation (Project No. 0023-2019-0005) and the Russian Science Foundation, grant 22-22-00570. I.A.K. thanks the Russian Science Foundation (grant No. 19-73-00237) for the financial support of the development of T-USPEX method and anharmonic phonon density of states calculation algorithm. S.W.T was supported by NSF Cooperative Agreement No. DMR-1157490/1644779 and by the State of Florida. We acknowledge the support of the HLD at HZDR, member of the European Magnetic Field Laboratory (EMFL). We also thank Dr. E. Talantsev (IMP RAS) for calculations within two-gap models, and Prof. Artem R. Oganov for help in using the USPEX code.

Conflict of Interest

The authors declare no conflict of interest.

Data availability

The raw and processed data required to reproduce these findings are available to download from GitHub: https://github.com/mark6871/SnHx-Tin-hydrides/, and as Supporting Information for the manuscript.

References

- 1 Drozdov, A. P., Eremets, M. I., Troyan, I. A. *et al.* Conventional superconductivity at 203 kelvin at high pressures in the sulfur hydride system. *Nature* **525**, 73-76 (2015).
- 2 Drozdov, A. P., Kong, P. P., Minkov, V. S. *et al.* Superconductivity at 250 K in lanthanum hydride under high pressures. *Nature* **569**, 528-531 (2019).
- 3 Somayazulu, M., Ahart, M., Mishra, A. K. *et al.* Evidence for Superconductivity above 260 K in Lanthanum Superhydride at Megabar Pressures. *Phys. Rev. Lett.* **122**, 027001 (2019).
- 4 Semenok, D. V., Kvashnin, A. G., Ivanova, A. G. *et al.* Superconductivity at 161 K in thorium hydride ThH₁₀: Synthesis and properties. *Mater. Today* **33**, 36-44 (2020).
- 5 Troyan, I. A., Semenok, D. V., Kvashnin, A. G. *et al.* Anomalous High Temperature Superconductivity in YH₆. *Adv. Mater.* **33**, 2006832 (2021).
- 6 Kong, P., Minkov, V. S., Kuzovnikov, M. A. *et al.* Superconductivity up to 243 K in the yttrium-hydrogen system under high pressure. *Nat. Commun.* **12**, 5075 (2021).
- 7 Chen, W., Semenok, D. V., Huang, X. *et al.* High-Temperature Superconducting Phases in Cerium Superhydride with a *Tc* up to 115 K below a Pressure of 1 Megabar. *Phys. Rev. Lett.* **127**, 117001 (2021).
- 8 Ma, L., Wang, K., Xie, Y. *et al.* High-Temperature Superconducting Phase in Clathrate Calcium Hydride CaH₆ up to 215 K at a Pressure of 172 GPa. *Phys. Rev. Lett.* **128**, 167001 (2022).

- 9 Li, Z., He, X., Zhang, C. *et al.* Superconductivity above 200 K discovered in superhydrides of calcium. *Nat. Commun.* **13**, 2863 (2022).
- 10 Semenok, D. V., Kruglov, I. A., Savkin, I. A. et al. On Distribution of Superconductivity in Metal Hydrides. *Curr. Opin. Solid State Mater. Sci.* **24**, 100808-100817 (2020).
- 11 Naumova, A. S., Lepeshkin, S. V., Oganov, A. R. Hydrocarbons under Pressure: Phase Diagrams and Surprising New Compounds in the C–H System. *J. Phys. Chem. C* **123**, 20497-20501 (2019).
- 12 Yang, T., Liu, J., Liu, X. *et al.* Theoretical Prediction of CH_n Crystal Structures under High Pressures. *Crystals* **11**, 1499 (2021).
- 13 Duan, D., Liu, Y., Ma, Y. *et al.* Structure and superconductivity of hydrides at high pressures. *National Science Review* **4**, 121-135 (2017).
- 14 Strobel, T. A., Somayazulu, M., Hemley, R. J. Novel Pressure-Induced Interactions in Silane-Hydrogen. *Phys. Rev. Lett.* **103**, 065701 (2009).
- 15 Wang, S., Mao, H.-k., Chen, X.-J. *et al.* High pressure chemistry in the H₂-SiH₄ system. *Proc. Natl. Acad. Sci. U S A* **106**, 14763 (2009).
- 16 Kong, P. P., Drozdov, A. P., Eroke, E. *et al.* Pressure-induced superconductivity above 79 K in Si₂H₆ in *Book of abstracts of AIRAPT 26 joint with ACHPR 8 & CHPC 19.*(2017).
- 17 Davari Esfahani, M. M., Oganov, A. R., Niu, H. *et al.* Superconductivity and unexpected chemistry of germanium hydrides under pressure. *Phys. Rev. B* **95**, 134506 (2017).
- 18 Strobel, T. A., Chen, X.-J., Somayazulu, M. *et al.* Vibrational dynamics, intermolecular interactions, and compound formation in GeH₄–H₂ under pressure. *J. Chem. Phys.* **133**, 164512 (2010).
- 19 Zhong, G., Zhang, C., Chen, X. *et al.* Structural, Electronic, Dynamical, and Superconducting Properties in Dense GeH₄(H₂)₂. *J. Phys. Chem. C* **116**, 5225-5234 (2012).
- 20 Gao, G., Oganov, A. R., Li, P. *et al.* High-pressure crystal structures and superconductivity of Stannane (SnH₄). *Proc. Natl. Acad. Sci. U S A* **107**, 1317-1320 (2010).
- 21 Chen, B., Conway, L. J., Sun, W. *et al.* Phase stability and superconductivity of lead hydrides at high pressure. *Phys. Rev. B* **103**, 035131 (2021).
- 22 Cheng, Y., Zhang, C., Wang, T. *et al.* Pressure-induced superconductivity in H₂-containing hydride PbH₄(H₂)₂. *Sci. Rep.* **5**, 16475 (2015).
- 23 Zaleski-Ejgierd, P., Hoffmann, R., Ashcroft, N. W. High Pressure Stabilization and Emergent Forms of PbH₄. *Phys. Rev. Lett.* **107**, 037002 (2011).
- 24 Guigue, B., Loubeyre, P. No observation of lead hydride in the Pb–H system under pressure up to 140 GPa. *J. Appl. Phys.* **129**, 225901 (2021).
- 25 Hong, F., Shan, P. F., Yang, L. X. *et al.* Possible superconductivity at ∼70 K in tin hydride SnH_x under high pressure. *Mater. Today Phys.* **22**, 100596 (2022).
- 26 Ritter, C., J. Synthesis of stannane and deuterostannane. (VOLTAIX. LLC) the US patent WO/2012/021634 (2012).
- 27 Gavriliuk, A. G., Troyan, I. A., Ivanova, A. G. *et al.* Structural Transitions in Elemental Tin at Ultra High Pressures up to 230 GPa. *JETP Letters* **106**, 733-738 (2017).
- 28 Salamat, A., Garbarino, G., Dewaele, A. *et al.* Dense close-packed phase of tin above 157 GPa observed experimentally via angle-dispersive x-ray diffraction. *Phys. Rev. B* **84**, 140104 (2011).
- 29 Esfahani, M. M. D., Wang, Z., Oganov, A. R. *et al.* Superconductivity of novel tin hydrides (Sn(_n)H(_m)) under pressure. *Sci. Rep.* **6**, 22873 (2016).
- 30 Semenok, D. V., Chen, W., Huang, X. *et al.* Sr-Doped Superionic Hydrogen Glass: Synthesis and Properties of SrH₂₂. *Adv. Mater.* **34**, 2200924 (2022).
- 31 Hirsch, J. E., Marsiglio, F. Nonstandard superconductivity or no superconductivity in hydrides under high pressure. *Phys. Rev. B* **103**, 134505 (2021).
- 32 Semenok, D. V., Troyan, I. A., Sadakov, A. V. *et al.* Effect of Magnetic Impurities on Superconductivity in LaH₁₀. *Adv. Mater.* **34**, 2204038 (2022).
- 33 Semenok, D. V., Troyan, I. A., Kvashnin, A. G. *et al.* Superconductivity at 253 K in lanthanum-yttrium ternary hydrides. *Mater. Today* **48**, 18-28 (2021).
- 34 Chen, W., Semenok, D. V., Kvashnin, A. G. *et al.* Synthesis of molecular metallic barium superhydride: pseudocubic BaH₁₂. *Nat. Commun.* **12**, 273 (2021).

- 35 Sun, D., Minkov, V. S., Mozaffari, S. *et al.* High-temperature superconductivity on the verge of a structural instability in lanthanum superhydride. *Nat. Commun.* **12**, 6863 (2021).
- 36 Bloch, F. Zum elektrischen Widerstandsgesetz bei tiefen Temperaturen. Z. Physik 59, 208-214 (1930).
- 37 Bardeen, J., Cooper, L. N., Schrieffer, J. R. Theory of Superconductivity. *Phys. Rev.* **108**, 1175-1204 (1957).
- 38 Werthamer, N. R., Helfand, E., Hohenberg, P. C. Temperature and Purity Dependence of the Superconducting Critical Field, *Hc*₂. III. Electron Spin and Spin-Orbit Effects. *Phys. Rev.* **147**, 295-302 (1966).
- 39 Osmond, I., Buhot, J. oral reports in Conference on Science at Extreme Conditions. (2021).
- 40 Hunte, F., Jaroszynski, J., Gurevich, A. *et al.* Two-band superconductivity in LaFeAsO_{0.89}F_{0.11} at very high magnetic fields. *Nature* **453**, 903-905 (2008).
- 41 Yuan, H. Q., Singleton, J., Balakirev, F. F. *et al.* Nearly isotropic superconductivity in (Ba,K)Fe₂As₂. *Nature* **457**, 565-568 (2009).
- 42 Gasparov, V. A., Sidorov, N. S., Zver'kova, I. I. Two-gap superconductivity in ZrB₁₂: Temperature dependence of critical magnetic fields in single crystals. *Phys. Rev. B* **73**, 094510 (2006).
- 43 Khim, S., Lee, B., Kim, J. W. *et al.* Pauli-limiting effects in the upper critical fields of a clean LiFeAs single crystal. *Phys. Rev. B* **84**, 104502 (2011).
- 44 Wang, C., Yi, S., Cho, J.-H. Multiband nature of room-temperature superconductivity in LaH₁₀ at high pressure. *Phys. Rev. B* **101**, 104506 (2020).
- 45 Kuroki, K., Higashida, T., Arita, R. High-Tc superconductivity due to coexisting wide and narrow bands: A fluctuation exchange study of the Hubbard ladder as a test case. *Phys. Rev. B* **72**, 212509 (2005).
- 46 Semenok, D. Computational design of new superconducting materials and their targeted experimental synthesis Doctoral program in matraials science and engineering thesis, Skoltech, (2022).
- 47 Jeon, H., Wang, C., Liu, S. *et al.* Electron-phonon coupling and superconductivity in an alkaline earth hydride CaH₆ at high pressures. *arXiv:2111.10797* (2021).
- 48 Spivak, B., Zhou, F. Mesoscopic Effects in Disordered Superconductors near *Hc*₂. *Phys. Rev. Lett.* **74**, 2800-2803 (1995).
- 49 Galitski, V. M., Larkin, A. I. Disorder and Quantum Fluctuations in Superconducting Films in Strong Magnetic Fields. *Phys. Rev. Lett.* **87**, 087001 (2001).
- 50 Talantsev, E. F., Tallon, J. L. Universal self-field critical current for thin-film superconductors. *Nat. Commun.* **6**, 7820 (2015).
- 51 Hu, J., Rosenbaum, T. F. Classical and quantum routes to linear magnetoresistance. *Nat. Mater.* **7**, 697-700 (2008).
- 52 Klimov, N. N., Knyazev, D. A., Omel'yanovskii, O. E. *et al.* Interaction effects in conductivity of a two-valley electron system in high-mobility Si inversion layers. *Phys. Rev. B* **78**, 195308 (2008).
- 53 DREIZIN, Y. A., DYKHNE, A. M. Interaction effects in conductivity of a two-valley electron system in high-mobility Si inversion layers. *Sov. Phys. JETP* **36**, 127 (1973).
- 54 Dykhne, A. M. Conductivity of a Two-dimensional Two-phase System. Sov. Phys. JETP 32 (1971).
- 55 Gorskii, P. V. The Kapitza effect in crystals with a superlattice. *Physica i Technika polurpovodnikov* **38**, 864 (2004).
- 56 Legros, A., Benhabib, S., Tabis, W. *et al.* Universal T-linear resistivity and Planckian dissipation in overdoped cuprates. *Nat. Phys.* **15**, 142-147 (2019).
- 57 Ataei, A., Gourgout, A., Grissonnanche, G. *et al.* Electrons with Planckian scattering obey standard orbital motion in a magnetic field. *Nat. Phys.* **18**, 1420-1424 (2022).
- 58 Greene, R. L., Mandal, P. R., Poniatowski, N. R. *et al.* The Strange Metal State of the Electron-Doped Cuprates. *Annual Review of Condensed Matter Physics* **11**, 213-229 (2020).
- 59 Talantsev, E. F. Universal Fermi velocity in highly-compressed hydride superconductors. *Matter and Radiation at Extremes* **7**, 058403 (2022).
- 60 Drude, P. Zur Elektronentheorie der Metalle. Annalen der Physik 306, 566-613 (1900).
- 61 Drude, P. Zur Elektronentheorie der Metalle; II. Teil. Galvanomagnetische und thermomagnetische Effecte. *Annalen der Physik* **308**, 369-402 (1900).
- 62 Al'tshuler, B. L., Aronov, A. G., Larkin, A. I. *et al.* Anomalous magnetoresistance in semiconductors. *Zh. Eksp. Teor. Fiz.* **81**, 768-783 (1981).

- 63 Tikhonenko, F. V., Horsell, D. W., Gorbachev, R. V. et al. Weak Localization in Graphene Flakes. *Phys. Rev. Lett.* **100**, 056802 (2008).
- 64 Mell, H., Stuke, J. Negative magnetoresistance of amorphous semiconductors. *Journal of Non-Crystalline Solids* **4**, 304-310 (1970).
- 65 Van den dries, L., Van Haesendonck, C., Bruynseraede, Y. *et al.* Two-Dimensional Localization in Thin Copper Films. *Phys. Rev. Lett.* **46**, 565-568 (1981).
- 66 Appel, J. Atomic ordering and *Tc* of narrow-band superconducting alloys. *Phys. Rev B* **13**, 3203-3208 (1976).
- 67 Belli, F., Novoa, T., Contreras-García, J. *et al.* Strong correlation between electronic bonding network and critical temperature in hydrogen-based superconductors. *Nat. Commun.* **12**, 5381 (2021).
- 68 Chen, W., Huang, X., Semenok, D. V. *et al.* Enhancement of superconducting critical temperature realized in La-Ce-H system at moderate pressures. *arXiv:2203.14353* (2022).
- 69 Zhou, Y., Guo, J., Cai, S. *et al.* Quantum phase transition from superconducting to insulating-like state in a pressurized cuprate superconductor. *Nature Physics* **18**, 406-410 (2022).
- 70 Chu, C. W., Deng, L. Z., Lv, B. Hole-doped cuprate high temperature superconductors. *Phys. C (Amsterdam, Neth.)* **514**, 290-313 (2015).
- 71 Lee, P. A., Nagaosa, N., Wen, X.-G. Doping a Mott insulator: Physics of high-temperature superconductivity. *Rev. Mod. Phys.* **78**, 17-85 (2006).
- 72 Eliashberg, G. M. Interactions between electrons and lattice vibrations in a superconductor. *Sov. Phys. JETP* **11**, 696-702 (1959).
- 73 Migdal, A. B. Interaction between electrons and lattice vibrations in a normal metal. *Sov. Phys. JETP* **34**, 996 (1958).
- 74 Yuzbashyan, E. A., Altshuler, B. L. Breakdown of the Migdal-Eliashberg theory and a theory of lattice-fermionic superfluidity. *Phys. Rev. B* **106**, 054518 (2022).
- 75 Alexandrov, A. S., Krebs, A. B. Polarons in high-temperature superconductors. *Sov. Phys. Usp.* **35**, 345 (1992).
- 76 Talantsev, E. F., Mataira, R. C. Classifying superconductivity in ThH-ThD superhydrides/superdeuterides. *Mater. Res. Express* 7, 016003 (2020).
- 77 Talantsev, E. F. An approach to identifying unconventional superconductivity in highly-compressed superconductors. *Superconductor Science and Technology* **33**, 124001 (2020).
- 78 Talantsev, E. F. Classifying Charge Carrier Interaction in Highly Compressed Elements and Silane. *Materials (Basel)* **14**, 4322 (2021).
- 79 Talantsev, E. F. Unconventional superconductivity in highly-compressed unannealed sulphur hydride. *Results in Physics* **16**, 102993 (2020).
- 80 Kuzovnikov, M. A. V(P) equations of state of novel lanthanum and yttrium superhydrides in *ELBRUS2021*. (2021).

SUPPORTING INFORMATION

Non-Fermi-Liquid Behavior of Superconducting SnH₄

Ivan A. Troyan,¹ Dmitrii V. Semenok,^{2,*} Anna G. Ivanova,¹ Andrey V. Sadakov,³ Di Zhou,^{2,*} Alexander G. Kvashnin,⁴ Ivan A. Kruglov,^{5,6} Oleg A. Sobolevskiy,³ Marianna V. Lyubutina,¹ Dmitry S. Perekalin,⁷ Toni Helm,⁸ Stanley W. Tozer,⁹ Maxim Bykov,¹⁰ Alexander F. Goncharov,¹¹ Vladimir M. Pudalov,^{3,12} and Igor S. Lyubutin^{1,*}

Shubnikov Institute of Crystallography, Federal Scientific Research Center Crystallography and Photonics, Russian Academy of Sciences, 59 Leninsky Prospekt, Moscow 119333, Russia

² Center for High Pressure Science and Technology Advanced Research (HPSTAR), Beijing 100094, China

³ P. N. Lebedev Physical Institute, Russian Academy of Sciences, Moscow 119991, Russia

⁴ Skolkovo Institute of Science and Technology, Skolkovo Innovation Center, Bolshoi Blv. 30, Building 1, Moscow 121205, Russia

Dukhov Research Institute of Automatics (VNIIA), Moscow 127055, Russia
 Moscow Institute of Physics and Technology, 9 Institutsky Lane, Dolgoprudny 141700, Russia

⁷ A.N. Nesmeyanov Institute of Organoelement Compounds, Russian Academy of Sciences, 28 Vavilova str., Moscow 119334, Russia

8 Hochfeld-Magnetlabor Dresden (HLD-EMFL) and Würzburg-Dresden Cluster of Excellence, Helmholtz-Zentrum Dresden-Rossendorf (HZDR), Dresden 01328, Germany

⁹ National High Magnetic Field Laboratory, Florida State University, Tallahassee, Florida 32310, USA

¹⁰ Institute of Inorganic Chemistry, University of Cologne, Cologne 50939, Germany

¹¹ Earth and Planets Laboratory, Carnegie Institution for Science, 5241 Broad Branch Road NW, Washington, D.C. 20015, United States

¹² National Research University Higher School of Economics, Moscow 101000, Russia

Corresponding Authors: Di Zhou (di.zhou@hpstar.ac.cn), Dmitrii Semenok (dmitrii.semenok@hpstar.ac.cn), Igor S. Lyubutin (lyubutinig@mail.ru)

Contents

1. Methods	S2
2. Crystal structure search	So
3. X-ray diffraction and unit cell parameters of tin hydrides	S8
4. Raman spectra	S23
5. Electron and phonon band structures of tin hydrides	S2:
6. Transport and superconducting properties	S2′
7.Eliashberg functions	S31
8.Elastic properties	S34
References	S3 ⁴

1. Methods

1.1. Theory

The computational predictions of thermodynamic stability of the Sn–H phases at high pressures of 180 and 200 GPa were carried out using the variable-composition evolutionary algorithm USPEX ¹⁻³. The first generation, consisting of 80 structures, was produced using the random symmetric ³ and random topology ⁴ generators, whereas all subsequent generations contained 20% of random structures and 80% of structures created using heredity, softmutation, and transmutation operators.

The evolutionary searches were combined with structure relaxations using the density functional theory (DFT) 5,6 within the Perdew–Burke–Ernzerhof (PBE) generalized gradient approximation (GGA) functional 7 and the projector augmented wave method 8,9 as implemented in the VASP code $^{10-12}$. The kinetic energy cutoff for plane waves was 600 eV. The Brillouin zone was sampled using Γ -centered k-points meshes with a resolution of $2\pi \times 0.05$ Å $^{-1}$. The same parameters were used to calculate the equations of state of the discovered phases. We also calculated the phonon densities of states of the studied materials using the finite displacements method (VASP and PHONOPY 13,14). This methodology is similar to that used in our previous works 15,16 .

The calculations of the critical temperature of superconductivity $T_{\rm C}$ were carried out using Quantum ESPRESSO (QE) package ^{17,18}. We used the tetrahedron method with an offset q-point grid in order to avoid the singularity at $q = \Gamma$. The phonon frequencies and electron–phonon coupling (EPC) coefficients were computed using the density functional perturbation theory ¹⁹, employing the plane-wave pseudopotential method and the PBE exchange–correlation functional. The critical temperature ($T_{\rm C}$) was calculated using the Allen–Dynes formula ²⁰.

The dynamic stability and phonon density of states of Sn₈H₃₀, Sn₁₂H₄₅ and SnH₁₄ were studied using classical molecular dynamics and interatomic potentials (MTP) based on machine learning ²¹. It was demonstrated that the MTP can be used to calculate the phonon properties of materials ²². Moreover, within this approach we can explicitly take into account the anharmonicity of hydrogen vibrations.

To train the potential, we first simulated two models of cubic SnH_4 , Sn_8H_{30} and $Sn_{12}H_{45}$, as well as SnH_{14} in quantum molecular dynamics in an NPT ensemble at a temperature of 2000 K, with a duration of 5 picoseconds using the VASP code $^{10\text{-}12}$. We used the PAW PBE pseudopotentials for the H and Sn atoms, $2\pi \times 0.06 \text{ Å}^{-1}$ k-mesh with a cutoff energy of 400 eV. For training of the MTP, a set of structures of tin hydrides was chosen using active learning 23 . We checked the dynamic stability of Sn_8H_{30} , $Sn_{12}H_{45}$ and SnH_{14} using the obtained MTPs via several runs of molecular dynamics calculations at 300 K. First, the NPT dynamics simulations were performed in a supercell with about 1000 atoms for 40 picoseconds. During the last 20 picoseconds, the cell parameters were averaged. At the second step, the coordinates of the atoms were averaged within the NVT dynamics with a duration of 20 picoseconds and the final structure was symmetrized.

Then, the phonon density of states (DOS) was calculated within the MTP using the velocity autocorrelator (VACF) separately for each type of atoms ²⁴:

$$g(\vartheta) = 4 \int_0^\infty \cos(2\pi\vartheta t) \frac{\langle \overline{\vartheta(0)\vartheta(t)} \rangle}{\langle \overline{\vartheta(0)}^2 \rangle} dt, \tag{S1}$$

where ϑ is the frequency. The velocity autocorrelator was calculated using molecular dynamics, then the phonon DOS was obtained.

The critical temperature of superconductivity $(T_{\rm C})$ was estimated using the Allen-Dynes formula

$$T_c = \omega_{log} \frac{f_1 f_2}{1.2} \exp\left(\frac{-1.04(1+\lambda)}{\lambda - \mu^* - 0.62\lambda\mu^*}\right), \tag{S2}$$

where product of Allen-Dynes coefficients f_1 and f_2 is

$$f_1 f_2 = \sqrt[3]{1 + \left(\frac{\lambda}{2.46(1 + 3.8\mu^*)}\right)^{\frac{3}{2}}} \cdot \left(1 - \frac{\lambda^2 (1 - \omega_2/\omega_{log})}{\lambda^2 + 3.312(1 + 6.3\mu^*)^2}\right).$$
 (S3)

Polyhydrides at high pressure can be considered as binary alloys of metallic hydrogen and other elements, for example, metals. As demonstrated by J. Appel ²⁵ for binary disordered alloys, the electron-phonon interaction coefficient in this case can be expressed as

$$\lambda = -\sum_{\alpha,\beta} \frac{N_{\alpha}(0)N_{\beta}(0)}{N(0)} \cdot \frac{\langle V \rangle_{\alpha\beta}}{p_{\alpha}p_{\beta}},\tag{S4}$$

where $N_{\alpha}(0)$ and $N_{\beta}(0)$ are the partial contributions of metal (α) and hydrogen (β) atoms to the density of electronic states at the Fermi level (DOS). p_{α} and p_{β} are the probabilities of occupying certain positions by these atoms, and <V> are the averaged matrix elements of the electron-phonon interaction.

It should be taken into account that the strength of the electron-phonon interaction is the main driver of the critical temperature of superconductivity. Considering that $N_{\alpha}(0) = x N(0)$, $N_{\beta}(0) = (1-x) N(0)$, we can conclude that the highest λ achieved at x = 0.5 as maximum of x(1-x) function. This corresponds to results of many ab initio calculations: the contribution of hydrogen to the density of electronic states of a superhydride should be approximately 50% of the total density of states. If the contribution of hydrogen to N(0) is small (x << 0.5), we come to superconductivity in metals, which even at high pressure does not exceed $T_{\rm C} \sim 30$ K. If the contribution of hydrogen is large ($x \sim 1$) – this is the case of molecular polyhydrides (such as BaH₁₂, SrH₂₂), in which isolated hydrogen molecules weakly interact with each other.

There are several techniques to probe order parameter in superconductors. Some of them are based on tunnel effects – Josephson effect and Andreev reflection effects, while others are based on the investigating of the temperature dependence of the superfluid density (ρ_s). The latter proved to be a reliable tool to determine not only the quantity and values of energy gaps, but also the symmetry of order parameter – whether it has s-wave, d-wave or even more complex structure ²⁶. Temperature dependence $\rho_s(T)$ is usually deduced by means of either measuring directly the London penetration depth $\lambda(T)$, or measuring of lower critical field, or measuring self-field critical current density $J_C(T)$. Given all the limits and difficulties of DAC measurements we were only able to measure the self-field critical current. According to Ref. ^{26,27} the temperature dependence of $J_C(T)$ is related to the penetration depth $\lambda(T)$ by formulas

$$J_{c}(T) = \frac{\hbar}{4e\mu_{0}\lambda^{3}(T)} (\ln(\kappa) + 0.5) \cdot \left(\frac{\lambda(T)}{a} \tanh\left(\frac{a}{\lambda(T)}\right) + \frac{\lambda(T)}{b} \tanh\left(\frac{b}{\lambda(T)}\right)\right),$$

$$\frac{\lambda(T)}{\lambda(0)} = \sqrt{1 - \frac{1}{2k_{B}T} \int_{0}^{\infty} \cosh^{-2}\left(\frac{\sqrt{\varepsilon^{2} + \Delta^{2}(T)}}{2k_{B}T}\right)},$$

$$\Delta(T) = \Delta(0) \cdot \tanh\left(\frac{\pi k_{B}T}{\Delta(0)} \sqrt{\eta\left(\frac{\Delta C}{C}\right)\left(\frac{T_{C}}{T} - 1\right)}\right),$$
(S5)

where 2a – is the width of sample, 2b – is the thickness of sample, μ_0 is the permeability of free space, e is the electron charge, $\kappa = \lambda/\xi$ is the Ginsburg-Landau parameter, $\Delta(T)$ – the superconducting gap, $\eta = 2/3$ for s-wave superconductivity, and $\Delta C/C$ – is the specific heat capacity jump at the superconducting transition. In these equations, parameters b, $\Delta(0)$, $\lambda(0)$ and $\Delta C/C$ are refined parameters. The best fit is shown in Supporting Figure S17d.

1.2. Experiment

We used the diamond anvils with a 50 μ m culet beveled to 300 μ m at 8.5°, equipped with four ~200 nm thick Ta electrodes with ~80 nm gold plating that were sputtered onto the piston diamond. Rhenium or steel ring composite gaskets were used for electrical measurements, and a mixture of CaF₂/epoxy resin was used to insulate the gaskets from electrical leads. Sn pieces with a thickness of ~1–2 μ m were sandwiched between the electrodes and ammonia borane NH₃BH₃ (AB) layer. Ammonia borane served as a pressure-transmitting medium and simultaneously was a source of hydrogen at the laser heating of the sample. The laser heating of the samples above 1500 K at pressures of 170–180 GPa was done by several 100 μ s pulses and led to the formation of various Sn hydrides, whose structure was analyzed using the single-crystal (SCXRD ²⁸⁻³⁰) and powder X-ray diffraction (XRD). It should be noted that DACs used for XRD have a wide opening angle (60-80°), while DACs prepared for the transport studies cannot be used for XRD due to presence of Ta/Au electrodes and small opening angle.

The XRD patterns of tin hydrides were studies at the ID27, P02 and HPCAT beamlines of ESRF (Grenoble, France), PETRA III (Hamburg, Germany) and APS (Argonne, USA) respectively, using monochromatic synchrotron radiation and an imaging plate detector at room temperature. The X-ray beam was focused in a less than $3 \times 3 \,\mu m$ spot. The XRD data were analyzed and integrated using Dioptas software package (version 0.5) ³¹. The full profile analysis of the diffraction patterns and the calculation of the unit cell parameters were performed using JANA2006 software ³² with the Le Bail method ³³. The pressure in the DACs was determined via the Raman signal from diamond at room temperature ³⁴. We should note that pressure in all DACs changes during cooling from 300 K to 4 K by about 5-10 GPa.

Single crystal XRD was performed at the beamline 13 IDD (GSECARS, Advanced Photon Source, Argonne, USA). For the single-crystal XRD measurements samples were rotated around a vertical ω -axis in a range $\pm 32^{\circ}$. The diffraction images were collected with an angular step $\Delta \omega = 0.5^{\circ}$ and an exposure time of 5-10 s/frame. For analysis of the single-crystal diffraction data (indexing, data integration, frame scaling and absorption correction) we used the CrysAlisPro software package, version 1.171.42.54a. To calibrate an instrumental model in the CrysAlisPro software, i.e., the sample-to-detector distance, detector's origin, offsets of goniometer angles, and rotation of both X-ray beam and the detector around the instrument axis, we used a single crystal of orthoenstatite ((Mg_{1.93}Fe_{0.06})(Si_{1.93}, Al_{0.06})O₆, *Pbca* space group, a = 8.8117(2), b = 5.18320(10), and c = 18.2391(3) Å).

Magnetoresistance measurements under high magnetic fields were carried out in a 24 mm bore 72 T resistive pulse magnet (rise time of 15 ms) at the Helmholtz-Zentrum Dresden-Rossendorf (HZDR). Strands of the Litz wire glued to the silver paint were moved closer together to minimize open loop pickup. The DAC was encased with strips of 125 µm × 1 cm wide Kapton tape. All twisted pairs were fixed using the GE7031 varnish (Lake Shore, 50:50 toluene: methanol thinner). A flow He cryostat (VTI) was used, which made it possible to better control the DACs temperature. Cernox thermometers (Lake Shore Cernox X95809) were attached to the DAC body for measurements of the temperature. There was no observable heating from the ramping of the magnetic field at rates up to 100 T/sec at temperatures above 20 K. A high-frequency (3.33 and 33.3 kHz) lock-in amplifier technique was employed to measure the sample resistance in a 72 T pulsed magnet. The magnet can be used on very special occasions to 72 T, but is usually used to 65 T to extend its lifetime. For the measurements in high magnetic fields, we used a four-wire AC method with the excitation current of 0.5-1 mA ³⁵; the voltage drop across the sample was amplified by an instrumentation amplifier and detected by a lock-in amplifier. Comparing the up and down sweep resistance curves at various field sweep rates, no significant sample heating was observed during a ~150 ms long magnet pulse at temperatures above 35 K. In general, we used the same methodology as in the previous study of (La, Nd) H_{10} ³⁶.

Table S1. List of high-pressure DACs used in this experiment, samples loaded into them and products obtained.

U 1	1	· 1	1
DAC	Experiment	Sample	Products
DAC S1	ESRF-2017	Sn	hcp-Sn, bcc-Sn
DAC S2	ESRF-2017	SnH ₄ , cryogenically loaded stannane	fcc-SnH ₄ , hcp-Sn
DAC D2	PETRA-2020	Sn/NH ₃ BH ₃	bcc-Sn, hcp-Sn, fcc-SnH ₄ , C2/m-SnH ₁₄
DAC M2	PETRA-2020	Sn/NH ₃ BH ₃	C2/m-SnH ₁₄ , fcc-SnH ₆₋₈ , fcc-SnH ₄ , fcc-SnH ₂
DAC S3	APS-2022	Sn/NH ₃ BH ₃	C2-Sn ₁₂ H ₁₈ , fcc -SnH ₄

2. Crystal structure search

It should be noted that the formation of tin polyhydrides at high pressures is a process with just a little thermodynamic benefit. This is evidenced by the values of the enthalpy of formation of Sn hydrides, which are $\Delta H \sim 10$ –60 meV/atom ³⁷, whereas, those of other metal polyhydrides ΔH (X + mH₂ \rightarrow XH_{2m}) are of the order of hundreds meV/atom ³⁷. In addition, the low enthalpy of formation makes the chemical process more dependent on hyperfine effects such as the zero-point energy (ZPE), entropy factor, spin-orbit coupling (SOC), anharmonicity of the hydrogen sublattice, as well as the choice of pseudopotentials and exchange-correlation functional for DFT calculations. As a result, the real convex hull of the Sn-H system is difficult to predict from the first principles. This explains the failure of all previous theoretical studies of tin polyhydride formation at high pressure ^{37,38}.

To verify that common DFT approaches are poorly suited to predict the existence of stable tin hydrides, we performed a search for the most appropriate crystal structure for SnH₄ composition using USPEX code ^{1-3,39} at 180 and 200 GPa (Supporting Figure S1). As a result, the *P6/mmm*, *P6₃/mmc* and *I4/mmm* phases of SnH₄ were identified as the most thermodynamically favorable. However, no cubic tin tetrahydrides were found. Moreover, none of the theoretically proposed Sn polyhydrides can explain the diffraction pattern of the material obtained by compressing SnH₄ and indexed as a cubic *fcc* lattice (experiment ESRF-2017). However, if we assume that the stoichiometric ratio Sn:H is not 1:4, but 1:3.75 (Th₄H₁₅-like structure), which may be the result of a decomposition reaction,

$$8 \text{ SnH}_4 \rightarrow \text{Sn}_8 \text{H}_{30} + \text{H}_2,$$
 (S6)

then we can find a good approximation to the structural solution of the problem. The stoichiometry of Sn_4H_{15} allows for dynamically and thermodynamically stable cubic (fcc) metal lattices. The results of an evolutionary structural search among such compositions (up to supercells of $Sn_{32}H_{120}$) at 180 GPa are: $R\bar{3}m$ - $Sn_{12}H_{45}$ (distorted $Fd\bar{3}m$) and $Fd\bar{3}m$ - Sn_8H_{30} (Supporting Table S2, Figure 1c in the main text). Both structures are metals with unit cell volumes of about 19.7 Å³/atom at 180 GPa. They are dynamically stable if one considers anharmonic effects. Both of these phases lie close to the convex hull of Sn-H system and exhibit fcc-like XRD patterns. Generally speaking, the most stable tin hydride at pressures of 170-210 GPa is P63/mmc-SnH₄ (with and without SOC, ZPE and entropy contribution, Supporting Tables S3, S4). But since such a compound was not observed among the experimental diffraction patterns, we excluded this phase from the consideration. Then, the most thermodynamically stable phase (with accounting ZPE) is $Fd\bar{3}m$ -Sn₈H₃₀ at 180 GPa, but $R\bar{3}m$ -Sn₁₂H₄₅ at 200 GPa and 0 K. At 1000 K, the situation does not change: the cubic modification of $Fd\bar{3}m$ -Sn₈H₃₀ is still slightly above the convex hull at 200 GPa (Supporting Table S4). As shown below, the calculated parameters of the superconducting state of $Fd\bar{3}m$ -Sn₈H₃₀ are close to the experimental data.

Table S2. Calculated convex hull parameters of Sn-H system at 180 GPa and 0 K. E_{total} is the total DFT energy, E_{form} is the energy of formation, X = H/(Sn+H).

Phase	Number of Sn atoms	Number of H atoms	X	Etotal, eV	Eform, eV/atom
$P6_3/mmc$ -Sn	2	0	0	30.982	0
$Fd\overline{3}m$ - Sn ₈ H ₃₀	8	30	0.789	116.208	-0.043
$R\bar{3}m$ - Sn ₁₂ H ₄₅	12	45	0.789	174.352	-0.042
$I\overline{4}m2$ -SnH ₈	2	16	0.889	27.088	-0.036
C2/m-SnH ₁₂	2	24	0.923	25.686	-0.016
C2/m-SnH ₁₄	2	28	0.933	25.219	-0.002
<i>C</i> 2/ <i>m</i> -H	0	24	1	-4.879	0

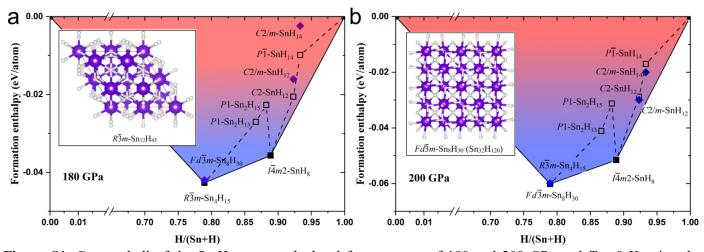


Figure S1. Convex hull of the Sn-H system calculated for pressures of 180 and 200 GPa and T = 0 K using the USPEX code without considering the ZPE. The most stable phase $P6_3/mmc$ -SnH₄ is excluded. The insets show the structures of $R\overline{3}m$ -Sn₁₂H₄₅ and $Fd\overline{3}m$ -Sn₈H₃₀ in the pressure range of 180–200 GPa. Consideration of ZPE and temperature effects has a little effect on the convex hull.

Table S3. Calculated convex hull parameters of Sn-H system at 200 GPa and 0 K. H_{form} is the DFT enthalpy of formation. ZPE is the zero-point energy in the harmonic approximation.

Phase	Sn atoms	H atoms	X	E(total), eV	E, eV/atom	E _{form} , eV/atom	ZPE, eV	E+ZPE, eV	H _{form} , eV/atom
P6 ₃ /mmc-Sn	2	0	0	34.366	17.183	0	0.051	34.417	0
$Fd\overline{3}m$ - Sn ₈ H ₃₀	8	30	0.789	135.678	3.570	-0.060	8.556	144.234	-0.064
$R\overline{3}m$ - Sn ₁₂ H ₄₅	12	45	0.789	203.533	3.571	-0.060	12.332	215.865	-0.072
$P6_3/mmc$ -SnH ₄	2	8	0.800	33.450	3.345	-0.105	2.320	35.770	-0.104
$I\overline{4}m2$ -SnH ₈	2	16	0.889	33.705	1.872	-0.052	4.034	37.738	-0.082
C2/m-SnH ₁₂	2	24	0.923	33.987	1.307	-0.030	6.750	40.738	-0.034
C2/m-SnH ₁₄	2	28	0.933	34.321	1.144	-0.017	7.847	42.168	-0.021
<i>C</i> 2/ <i>m</i> -H	0	24	1	0.400	0.017	0	6.794	7.194	0

Table S4. Extended convex hull parameters of Sn-H system at 200 GPa and 300-1000 K. F_{vib} is the vibrational energy, G_{form} is the Gibbs free energy of formation.

Phase		F _{vib} , eV/atom			G _{form} , eV/atom			
Temperature	300 K	500 K	1000 K	300 K	500 K	1000 K		
P6 ₃ /mmc-Sn	-0.164	-0.379	-1.076	0	0	0		
$Fd\overline{3}m$ - Sn ₈ H ₃₀	-0.485	-1.295	-4.849	-0.058	-0.049	-0.026		
$R\bar{3}m$ - Sn ₁₂ H ₄₅	-0.712	-1.995	-7.648	-0.066	-0.059	-0.041		
$P6_3/mmc$ -SnH ₄	-0.098	-0.284	-1.150	-0.097	-0.086	-0.059		
$I\overline{4}m2$ -SnH ₈	-0.105	-0.342	-1.577	-0.077	-0.070	-0.051		
C2/m-SnH ₁₂	-0.134	-0.440	-2.118	-0.031	-0.025	-0.013		
C2/m-SnH ₁₄	-0.154	-0.512	-2.494	-0.020	-0.015	-0.007		
<i>C</i> 2/ <i>m</i> -H	-0.038	-0.273	-1.577	0	0	0		

Thus, in this section, we showed a vivid example of how far the results of theoretical DFT calculations can differ from the results of experiments at high pressure. Although we succeeded to find a satisfactory dynamically stable model (Sn_8H_{30}) to describe the properties of experimental cubic SnH_4 , we have failed to solve the problem of thermodynamic stability of Sn polyhydrides at high pressure (Supporting Figure S1). Strictly speaking, at a given crystal structure $P6_3/mmc$ - SnH_4 , all experimentally found Sn hydrides appear to be displaced from the convex hull at 180-200 GPa and, in terms of the current level of theoretical structural search, can exist only as metastable phases. Obviously, there must be some unusual effect that stabilizes the cubic modification of SnH_4 , but this problem is beyond the scope of this study.

3. X-ray diffraction and unit cell parameters of tin hydrides

Reaction products (APS-2022 experiment, Table S4) contained multiple good-quality single-crystalline domains of novel phases (Supporting Figure S2) and it was possible to find orientation matrices of several single crystals following well established procedures (see Ref. ⁴⁰ for more details on the procedure).

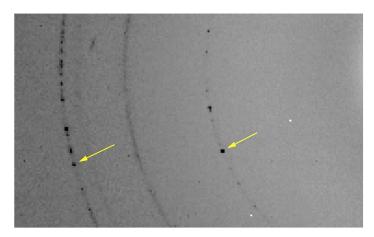


Figure S2. Example of the diffraction pattern showing reflections originating from small single crystals, APS-2022. These peaks are distinct and can be separated from the "bad powder" rings.

The dominant phase was initially indexed using a cubic F-centered lattice with a = 5.780(5) Å at 171 GPa. This lattice at the first glance does not correspond to any of the theoretically predicted Sn-H phases. Nevertheless, one should take into account that XRD gives information on the positions of heavy atoms only due to the great difference in the atomic scattering factors of Sn and H. Therefore, it is not excluded that detection of weak superlattice reflections is beyond the current experimental capabilities. Unconstrained refinement of the unit cell parameters based on 42 single-crystal reflections revealed slight deviation of the cubic lattice parameters from each other: a = 5.780(5) Å, b = 5.796(10) Å, c = 5.775(9) Å, which might indicate that the lattice is indeed distorted.

A sequence of lattice transformations defined by the following matrices allows to convert the F-centered lattice to a monoclinic C-centered lattice and refine unit cell with a better final figure of merit:

$$cF \to mI \begin{pmatrix} 0.5 & 0 & 0.5 \\ -0.5 & 0 & 0.5 \\ 0 & -1 & 0 \end{pmatrix}; mI \to mC \begin{pmatrix} -1 & 0 & -1 \\ 0 & 1 & 0 \\ 1 & 0 & 0 \end{pmatrix}; cF \to mC \begin{pmatrix} -0.5 & 1 & -0.5 \\ -0.5 & 0 & 0.5 \\ 0.5 & 0 & 0.5 \end{pmatrix}$$

The *C*-centered lattice obtained by the transformation of *F*-centered cubic lattice agrees well with the predicted $C2-\mathrm{Sn_{12}H_{18}}$ phase with a=7.083(15) Å, b=4.082 Å, c=4.090 Å, $\beta=125.1^\circ$. Structure refinement in a cubic $Fm\overline{3}m$ symmetry (a=5.780(5) Å) with Sn occupying Wyckoff sites 4b and 8c converges with an excellent agreement factor $R_1=5.83\%$, confirming the pseudocubic arrangement of Sn atoms in the calculated $C2-\mathrm{Sn_{12}H_{18}}$ structure (Table S4, Figure S3).

The second phase ($fcc \, SnH_4$) in the sample at 171 GPa was initially indexed with a cubic F-centered lattice with a = 4.244(3) Å. Crystal structure refinement suggests fcc arrangement of Sn atoms with a space group $Fm\bar{3}m$ and Sn occupying Wyckoff site 4a ($R_1 = 4.75$ %). This lattice parameter is exactly half of that of the predicted $Fd\bar{3}m$ -Sn₈H₃₀ phase. However, due to the low atomic scattering factor of hydrogen, the supercell could not be confirmed by single-crystal XRD.

Impurity reflections in the XRD patterns (Figure 2 in the main text) can be explained by orthorhombically distorted $Im\overline{3}m$ structure. However, as can be seen from the data of Supporting Tables S5, S7, S8, the resulting volume $V \sim 23.5\text{-}24.1 \text{ Å}^3$ (Z = 2) is too small for bcc-Sn. Better agreement with the unit cell volume was obtained for $P6_3/mmc$ -Sn structure (for example, a = 2.633 Å, c = 4.581 Å, $V = 27.5 \text{ Å}^3$, Z = 2), but the refinement quality is lower. This indicates that the strong reflection at $2\theta \approx 8^\circ$ (Figures 2a, d) may have a source other than residual tin.

In our experiment with DAC M2, in addition to SnH₁₄, several other tin hydrides were also detected. They can be indexed as two cubic phases: fcc-1 (Supporting Figure S5), and fcc-2 with a larger unit cell volume. The latter phase can also be indexed as pseudocubic I4/mmm (Supporting Figure S6). For the fcc-1 phase, indexing gives the unit cell volume $V \approx 16.5$ -17.1 Å³/Sn at 180 GPa, which is approximately 3 Å³/Sn less than it is necessary for the SnH₄ composition. Such a value of the unit cell volume better matches the composition of SnH₂ where Sn has a formal valence of +2. For the second cubic phase fcc-2, refinement gives the unit cell volume V = 23.5-24.1 Å³/Sn (Supporting Table S5), which corresponds to the composition SnH_{6+x} (x = 0 - 0.5, see Figure 2e), or the previously predicted stable tetragonal SnH_{8-x} ³⁷.

Table S5. Summary table of the XRD experiments (without SnH_{14} and Sn). Unit cell parameters of $Fd\overline{3}m$ - Sn_8H_{30} and C2- $Sn_{12}H_{18}$ compounds obtained in three experiments at different pressures are shown. Unit cell parameters of fcc-1 phase (SnH_2), fcc-2 (SnH_6 or SnH_{8-x}) and a gasket (e.g., bcc-Fe (?), one diffusive ring), obtained at PETRA-2020, are also shown. The experimental error in the pressure value is within 5 GPa.

Phase	F	√d3m-Sn ₈ H ₃	0	C2-	Sn ₁₂ H ₁₈ ($\beta = 124.46$	o, fixed)	bc	<i>bcc</i> -Sn	
Experiment	a, Å $(Z = 32)$	$V, Å^3$ $(Z = 32)$	<i>V</i> , Å ³ /Sn	a, Å	b, Å	c, Å	<i>V</i> , Å ³ /Sn	a, Å	(Z = 2)	
ESRF-2017,	, ,								, , , ,	
180 GPa	8.567	628.7	19.64					2.996	26.9	
PETRA-2020, 170 GPa	8.619	640.5	20.0	-	-	-	-	3.012	27.32	
APS-2022, 192-196 GPa	8.5075	615.7	19.24	7.007	4.095	4.020	15.85	-	-	
APS-2022, 165-171 GPa	8.689	656.0	20.5	7.097	4.175	4.130	16.82	-	-	
APS-2022, 150-155 GPa	8.719	662.8	21.2	7.087	4.205	4.100	16.85		-	
Phase		fcc-1 SnH ₂		fcc-2, S	_	seudocubi SnH _{8-x}	ic I4/mmm-	bcc gasket (Fe ?)		
PETRA-2020	a, Å $(Z = 32)$	$V, Å^3$ $(Z = 32)$	<i>V</i> , Å ³ /Sn	a, Å	c, Å	$V_{\text{tet}}, \text{Å}^3$ $(Z = 2)$	V _{cub} ,Å ³ /Sn	a, Å	V, Å ³	
185 GPa	8.159 8.165	543.13 544.33	16.97 17.01	3.241	4.591	48.22	24.11	2.365	13.23	
180-185 GPa	8.180	547.34	17.10	3.229	4.614	48.11	24.11	2.365	13.23	
	8.130	537.37	16.79	2 220	4 577	47.74				
190-196 GPa	8.140	539.35	16.85	3.229	4.577	47.74 47.90	23.95	2.360	13.14	
	8.135	538.33	16.82	3.233	4.582	47.90				
201-208 GPa	8.1060	532.62	16.64	3.215	4.557	47.11	23.58	2.345	12.90	
201-200 Ora	6.1000	332.02	10.04	3.213	7.337	4/.11	23.30	2.352	13.01	
208-210 GPa	8.090	529.47	16.54	3.195	4.561	46.57	23.47	2.342	12.87	

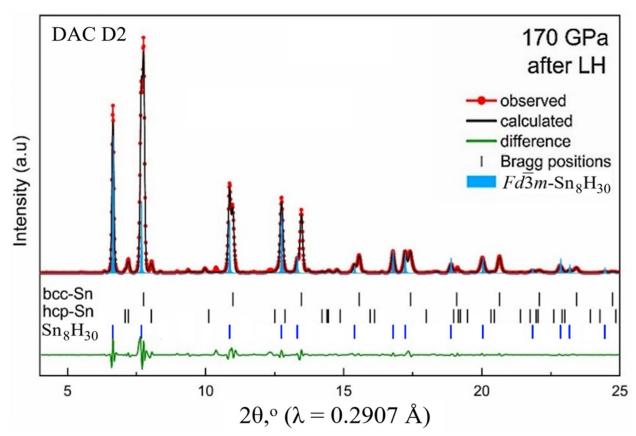


Figure S3. Experimental X-ray diffraction pattern of the results of laser heating of Sn/AB at a pressure of 170 GPa (DAC D2). XRD pattern was obtained at PETRA III in 2020. Cubic SnH₄ compound as the main product, along with unreacted Sn in hexagonal (hcp) and cubic (bcc) modifications are clearly seen. The Bragg peaks positions for the theoretical model, $Fd\bar{3}m$ -Sn₈H₃₀, are also shown.

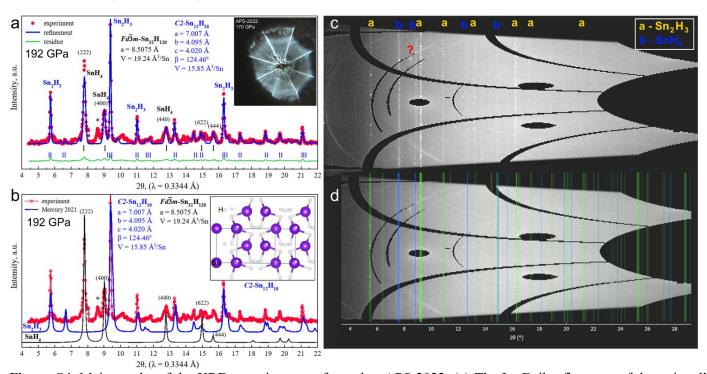


Figure S4. Main results of the XRD experiment performed at APS-2022. (a) The Le Bail refinement of the unit cell parameters of $C2\text{-Sn}_{12}H_{18}$ (= Sn₂H₃) and cubic SnH₄ (theoretical model is $Fd\overline{3}m\text{-Sn}_{32}H_{120} = \text{Sn}_8\text{H}_{30}$) phases at a pressure of 192 GPa. Unidentified reflections are marked by asterisks. The experimental data, fitted line, and residues are shown in red, blue, and green, respectively. Inset: sample photograph at 171 GPa. (b) Comparison of experimental (red line) and calculated (blue and black lines) XRD patterns for Sn₁₂H₁₈ (= Sn₂H₃) and SnH₄ (theoretical model is $Fd\overline{3}m\text{-Sn}_{32}H_{120}$), respectively. Inset: crystal structure of $C2\text{-Sn}_{12}H_{18}$. (c, d) Diffraction images ("cake") where one can see two groups of diffraction rings: relatively diffuse rings (b) corresponding to the cubic SnH₄, which can be obtained in pure form, and the second fraction, "dotted" rings (a) corresponding to Sn₁₂H₁₈ (= Sn₂H₃).

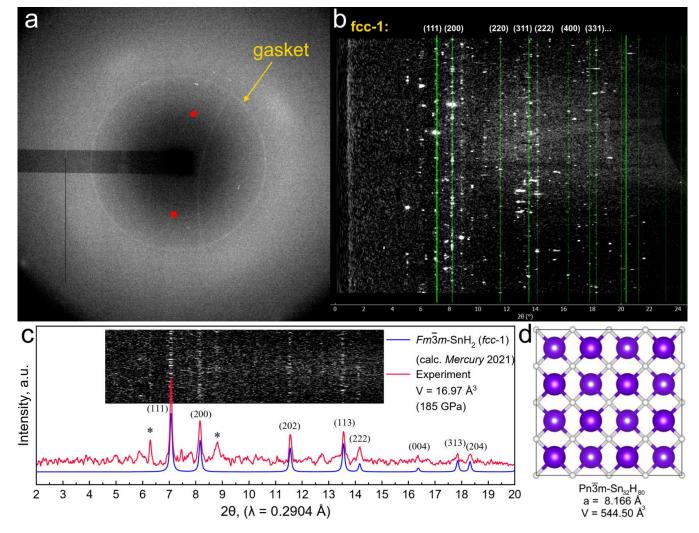


Figure S5. XRD patterns of hydrides synthesized in DAC M2 at 185 GPa. (a) A characteristic continuous diffraction ring from the gasket material. (b) A characteristic "dotted" pattern (coarse-crystalline) of tin hydrides. Green lines correspond to the fcc-1 phase (SnH₂). (c) X-ray diffraction pattern of the sample in DAC M2 at 185 GPa collected at a wavelength of $\lambda = 0.2904$ Å. Comparison of experimental and calculated XRD reflection intensities for the fcc-1 phase (refined using prototype $Fm\overline{3}m$ -YH₂) is shown. Inset: diffraction image ("cake"). Unidentified reflections are marked by asterisks. (d) Crystal structure of one alternative candidate for the fcc-1 phase, Sn₃₂H₈₀ = SnH_{2.5} which has a unit cell volume close to the experimental one.

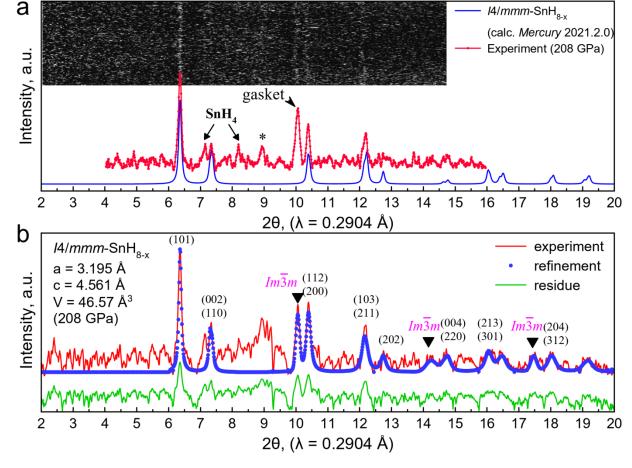


Figure S6. X-ray diffraction pattern of the edge of sample in DAC M2 at 208 GPa collected at a wavelength of $\lambda = 0.2904$ Å. (a) Comparison of experimental and calculated XRD intensities for the *fcc*-2 phase (refined as pseudocubic *I4/mmm*-SnH_{8-x}, Z = 2). Inset: the diffraction image ("cake"). (b) The Le Bail refinement of the unit cell parameters of the *I4/mmm*-SnH_{8-x} (*fcc*-2) phase. Unidentified reflections are marked by asterisks. The experimental data, fitted line, and residues are shown in red, blue, and green, respectively. "*Im* $\bar{3}m$ " denotes the unidentified reflection from the gasket or material of the DAC.

Table S6. Experimental and predicted structures (cif files) of various tin hydrides.

fcc SnH ₄ at 171 GPa (experiment)	C2/m-SnH ₁₄ at 180 GPa (calculations)
data_cf_snh4	data_SnH14_180GPa
_audit_creation_date 2023-01-26	symmetry cell setting monoclinic
_audit_creation_method	symmetry space group name H-M 'C 2/m'
;	_symmetry_Int_Tables_number 12
Olex2 1.5	space_group_name_Hall '-C 2y'
(compiled 2022.04.07 svn.rca3783a0 for OlexSys, GUI svn.r6498)	loop_
shelx SHELXL version number '2014/7'	_symmetry_equiv_pos_site_id
audit contact author address ?	symmetry equiv pos as xyz
audit contact author email ?	
audit contact author name "	1 x,y,z
audit contact author phone ?	2 -x,y,-z
publ contact author id orcid ?	3 -x,-y,-z
_publ_section_references	4 x,-y,z
;	5 1/2+x,1/2+y,z
Dolomanov, O.V., Bourhis, L.J., Gildea, R.J, Howard, J.A.K. &	6 1/2-x,1/2+y,-z
Puschmann, H.	7 1/2-x,1/2-y,-z
(2009), J. Appl. Cryst. 42, 339-341.	8 1/2+x,1/2-y,z
G1 11 1 GM (2015) A + G + G71 2 0	_cell_length_a 7.756
Sheldrick, G.M. (2015). Acta Cryst. C71, 3-8.	cell length b 2.871
; chemical name common ?	cell length c 3.797
chemical name systematic 'tin hydride'	cell_angle_alpha 90
chemical formula moiety '0.021(Sn48)'	cell angle beta 118.34
chemical formula sum 'Sn'	cell angle gamma 90
chemical_formula_weight 118.69	_cell_volume 74.42

```
chemical melting point
                                                                      loop
loop
                                                                      atom site label
 _atom_type_symbol
                                                                      _atom_site_type_symbol
 _atom_type description
                                                                      atom site fract x
 atom type scat dispersion real
                                                                      atom site fract y
 atom type scat dispersion imag
                                                                      _atom_site fract z
 atom type scat source
                                                                      _atom_site_U_iso_or_equiv
'Sn' 'Sn' -0.6925 2.4050
'International Tables Vol C Tables 4.2.6.8 and 6.1.1.4'
                                                                      atom site thermal displace type
                                                                      Sn1 Sn 0 0.5 0 0.0000 Uiso
shelx space group comment
                                                                      H1 H 0.26312 0.22116 0.40715 0.0000 Uiso
                                                                      H3 H -0.18543 0 -0.01272 0.0000 Uiso
The symmetry employed for this shelxl refinement is uniquely defined
                                                                      H4 H -0.06856 0 -0.3698 0.0000 Uiso
by the following loop, which should always be used as a source of
                                                                      H6 H 0 0.5 0.5 0.0000 Uiso
symmetry information in preference to the above space-group names.
                                                                      H2 H 0.13137 0.5 -0.2995 0.0000 Uiso
They are only intended as comments.
                                                                      H5 H -0.30277 0.5 -0.1822 0.0000 Uiso
_space_group_crystal_system
                                 'cubic'
                                                                      H1 H -0.26312 0.22116 -0.40715 0.0000 Uiso
_space_group_IT_number
                                225
                                                                      H3 H 0.18543 0 0.01272 0.0000 Uiso
                                  'F m -3 m'
space group name H-M alt
                                                                      H4 H 0.06856 0 0.3698 0.0000 Uiso
                                '-F 4 2 3'
space group name Hall
                                                                      H2 H -0.13137 0.5 0.2995 0.0000 Uiso
loop
                                                                      H5 H 0.30277 0.5 0.1822 0.0000 Uiso
 _space_group_symop_operation_xyz
'x, y, z'
                                                                      H1 H -0.26312 0.77884 -0.40715 0.0000 Uiso
'-x, -y, z'
                                                                      H1 H 0.26312 0.77884 0.40715 0.0000 Uiso
'-x, y, -z'
                                                                      Sn1 Sn 0 -0.5 0 0.0000 Uiso
'x, -y, -z'
                                                                      Sn1 Sn 0 0.5 1 0.0000 Uiso
'z, x, y'
                                                                      Sn1 Sn 0 1.5 0 0.0000 Uiso
'z, -x, -y
                                                                      H3 H -0.18543 1 -0.01272 0.0000 Uiso
'-z, -x, y
                                                                      H3 H 0.18543 1 0.01272 0.0000 Uiso
'-z, x, -y
'y, z, x'
                                                                      H4 H -0.06856 1 -0.3698 0.0000 Uiso
'-y, z, -x'
                                                                      H4 H 0.06856 1 0.3698 0.0000 Uiso
'y, -z, -x'
                                                                      H6 H 0 0.5 -0.5 0.0000 Uiso
'-y, -z, x'
                                                                      H7 H 0 0 0.5 0.0000 Uiso
'y, x, -z'
 '-y, -x, -z'
                                                                      #END
'y, -x, z'
'-y, x, z'
                                                                      Symmetrized Sn sublattice (R-3m) in C2-Sn_{12}H_{18} at
'x, z, -y'
                                                                      200 GPa (calculations)
'-x, z, y'
'-x, -z, -y'
                                                                      # CIF file
'x, -z, y'
                                                                      # This file was generated by FINDSYM
'z, y, -x'
                                                                      # Harold T. Stokes, Branton J. Campbell, Dorian M. Hatch
'z, -y, x'
                                                                      # Brigham Young University, Provo, Utah, USA
'-z, y, x'
'-z, -y, -x'
'x, y+1/2, z+1/2'
                                                                      data findsym-output
'-x, -y+1/2, z+1/2'
-x, y+1/2, -z+1/2
'x, -y+1/2, -z+1/2'
                                                                      symmetry space group name H-M 'R -3 2/m (hexagonal
'z, x+1/2, y+1/2'
                                                                      axes)'
z, -x+1/2, -y+1/2
                                                                      symmetry_Int_Tables_number 166
'-z, -x+1/2, y+1/2'
'-z, x+1/2, -y+1/2'
'y, z+1/2, x+1/2'
                                                                      cell length a
                                                                                          4.07646
'-y, z+1/2, -x+1/2
                                                                      cell length b
                                                                                          4.07646
'y, -z+1/2, -x+1/2'
                                                                      _cell_length c
                                                                                          9.94541
'-y, -z+1/2, x+1/2'
'y, x+1/2, -z+1/2'
                                                                      cell angle alpha 90.00000
'-y, -x+1/2, -z+1/2
                                                                      cell angle beta 90.00000
'y, -x+1/2, z+1/2'
                                                                      _cell_angle_gamma 120.00000
'-y, x+1/2, z+1/2'
                                                                      _cell_volume 143.1264
'x, z+1/2, -y+1/2
'-x, z+1/2, y+1/2'
'-x, -z+1/2, -y+1/2'
                                                                      loop_
'x, -z+1/2, y+1/2'
                                                                      space_group_symop_operation_xyz
'z, y+1/2, -x+1/2'
z, -y+1/2, x+1/2
                                                                      x,y,z
'-z, y+1/2, x+1/2'
                                                                      -y,x-y,z
'-z, -y+1/2, -x+1/2
                                                                      -x+y,-x,z
'x+1/2, y, z+1/2'
                                                                      y,x,-z
-x+1/2, -y, z+1/2
```

```
-x+1/2, y, -z+1/2
                                                                        -x,-x+y,-z
'x+1/2, -y, -z+1/2
                                                                        x-y,-y,-z
'z+1/2, x, y+1/2'
                                                                        -x,-y,-z
'z+1/2, -x, -y+1/2'
'-z+1/2, -x, y+1/2
                                                                        y,-x+y,-z
'-z+1/2, x, -y+1/2'
                                                                        x-y,x,-z
y+1/2, z, x+1/2
                                                                        -y,-x,z
'-y+1/2, z, -x+1/2'
                                                                        x,x-y,z
y+1/2, -z, -x+1/2
'-y+1/2, -z, x+1/2'
                                                                        -x+y,y,z
'y+1/2, x, -z+1/2'
                                                                        x+1/3,y+2/3,z+2/3
-y+1/2, -x, -z+1/2
                                                                        -y+1/3,x-y+2/3,z+2/3
y+1/2, -x, z+1/2
                                                                        -x+y+1/3,-x+2/3,z+2/3
'-y+1/2, x, z+1/2'
'x+1/2, z, -y+1/2'
                                                                        y+1/3,x+2/3,-z+2/3
'-x+1/2, z, y+1/2'
                                                                        -x+1/3, -x+y+2/3, -z+2/3
-x+1/2, -z, -y+1/2
                                                                        x-y+1/3,-y+2/3,-z+2/3
x+1/2, -z, y+1/2
z+1/2, y, -x+1/2
                                                                        -x+1/3,-y+2/3,-z+2/3
z+1/2, -y, x+1/2
                                                                        y+1/3,-x+y+2/3,-z+2/3
'-z+1/2, y, x+1/2
                                                                        x-y+1/3, x+2/3, -z+2/3
'-z+1/2, -y, -x+1/2'
                                                                        -y+1/3,-x+2/3,z+2/3
x+1/2, y+1/2, z'
-x+1/2, -y+1/2, z'
                                                                        x+1/3,x-y+2/3,z+2/3
'-x+1/2, y+1/2, -z'
                                                                        -x+y+1/3,y+2/3,z+2/3
x+1/2, -y+1/2, -z'
                                                                        x+2/3,y+1/3,z+1/3
'z+1/2, x+1/2, y'
                                                                        -y+2/3,x-y+1/3,z+1/3
'z+1/2, -x+1/2, -y'
'-z+1/2, -x+1/2, y'
                                                                        -x+y+2/3,-x+1/3,z+1/3
'-z+1/2, x+1/2, -y
                                                                        y+2/3,x+1/3,-z+1/3
'y+1/2, z+1/2, x'
                                                                        -x+2/3, -x+y+1/3, -z+1/3
'-y+1/2, z+1/2, -x'
y+1/2, -z+1/2, -x'
                                                                        x-y+2/3,-y+1/3,-z+1/3
-y+1/2, -z+1/2, x
                                                                        -x+2/3,-y+1/3,-z+1/3
y+1/2, x+1/2, -z'
                                                                        y+2/3,-x+y+1/3,-z+1/3
-y+1/2, -x+1/2, -z
                                                                        x-y+2/3,x+1/3,-z+1/3
y+1/2, -x+1/2, z'
-y+1/2, x+1/2, z'
                                                                        -y+2/3,-x+1/3,z+1/3
x+1/2, z+1/2, -y
                                                                        x+2/3,x-y+1/3,z+1/3
-x+1/2, z+1/2, y'
                                                                        -x+y+2/3,y+1/3,z+1/3
'-x+1/2, -z+1/2, -y'
'x+1/2, -z+1/2, y'
z+1/2, y+1/2, -x'
                                                                        loop
'z+1/2, -y+1/2, x'
                                                                        atom site label
'-z+1/2, y+1/2, x'
                                                                        _atom_site_type_symbol
'-z+1/2, -y+1/2, -x'
'-x, -y, -z'
                                                                        atom site fract x
'x, y, -z'
                                                                        atom site fract y
'x, -y, z'
                                                                        _atom_site_fract_z
'-x, y, z'
                                                                        atom site occupancy
'-z, -x, -y'
'-z, x, y'
                                                                        Sn1 Sn 0.00000 0.00000 -0.24147 1.00000
'z, x, -y'
                                                                        Sn2 Sn 0.00000 0.00000 0.00000 1.00000
'z, -x, y'
'-y, -z, -x'
'y, -z, x'
                                                                        R\overline{3}m-Sn<sub>12</sub>H<sub>45</sub> at 180 GPa (calculations)
'-y, z, x'
'y, z, -x'
'-y, -x, z'
                                                                        # CIF file
'y, x, z'
                                                                        # This file was generated by FINDSYM
'-y, x, -z'
                                                                        # Harold T. Stokes, Branton J. Campbell, Dorian M. Hatch
'y, -x, -z'
                                                                        # Brigham Young University, Provo, Utah, USA
'-x, -z, y'
'x, -z, -y
^{\prime}x,\,z,\,y^{\prime}
                                                                        data findsym-output
'-x, z, -y'
'-z, -y, x'
                                                                        _symmetry_space_group_name_H-M 'R -3 2/m (hexagonal
'-z, y, -x'
'z, -y, -x'
'z, y, x'
                                                                        _symmetry_Int_Tables_number 166
-x, -y+1/2, -z+1/2
'x, y+1/2, -z+1/2'
'x, -y+1/2, z+1/2'
                                                                        cell length a
                                                                                            6.05800
'-x, y+1/2, z+1/2'
```

```
'-z, -x+1/2, -y+1/2
                                                                     cell length b
                                                                                        6.05800
'-z, x+1/2, y+1/2'
                                                                                        7.37800
                                                                     cell length c
'z, x+1/2, -y+1/2'
                                                                     _cell_angle_alpha 90.00000
'z, -x+1/2, y+1/2'
                                                                     cell angle beta 90.00000
'-y, -z+1/2, -x+1/2
'y, -z+1/2, x+1/2'
                                                                     cell angle gamma 120.00000
'-y, z+1/2, x+1/2'
'y, z+1/2, -x+1/2'
                                                                    loop
'-y, -x+1/2, z+1/2'
'y, x+1/2, z+1/2'
                                                                     _space_group_symop_operation_xyz
'-y, x+1/2, -z+1/2'
                                                                    x,y,z
y, -x+1/2, -z+1/2
                                                                    -y,x-y,z
'-x, -z+1/2, y+1/2'
'x, -z+1/2, -y+1/2'
                                                                    -x+y,-x,z
'x, z+1/2, y+1/2'
                                                                    y,x,-z
'-x, z+1/2, -y+1/2'
                                                                    -x,-x+y,-z
'-z, -y+1/2, x+1/2
                                                                    x-y,-y,-z
'-z, y+1/2, -x+1/2'
z, -y+1/2, -x+1/2
                                                                    -x,-y,-z
'z, y+1/2, x+1/2'
                                                                    y,-x+y,-z
-x+1/2, -y, -z+1/2
                                                                    x-y,x,-z
x+1/2, y, -z+1/2
x+1/2, -y, z+1/2
                                                                    -y,-x,z
'-x+1/2, y, z+1/2'
                                                                    x,x-y,z
'-z+1/2, -x, -y+1/2'
                                                                    -x+y,y,z
'-z+1/2, x, y+1/2'
                                                                    x+1/3,y+2/3,z+2/3
z+1/2, x, -y+1/2
                                                                    -y+1/3,x-y+2/3,z+2/3
'z+1/2, -x, y+1/2'
'-y+1/2, -z, -x+1/2'
                                                                    -x+y+1/3,-x+2/3,z+2/3
y+1/2, -z, x+1/2
                                                                    y+1/3,x+2/3,-z+2/3
-y+1/2, z, x+1/2
                                                                    -x+1/3, -x+y+2/3, -z+2/3
'y+1/2, z, -x+1/2'
-y+1/2, -x, z+1/2
                                                                    x-y+1/3,-y+2/3,-z+2/3
'y+1/2, x, z+1/2'
                                                                    -x+1/3,-y+2/3,-z+2/3
'-y+1/2, x, -z+1/2
                                                                    y+1/3,-x+y+2/3,-z+2/3
y+1/2, -x, -z+1/2
                                                                    x-y+1/3,x+2/3,-z+2/3
-x+1/2, -z, y+1/2
'x+1/2, -z, -y+1/2'
                                                                    -y+1/3,-x+2/3,z+2/3
'x+1/2, z, y+1/2'
                                                                    x+1/3,x-y+2/3,z+2/3
-x+1/2, z, -y+1/2
                                                                    -x+y+1/3,y+2/3,z+2/3
'-z+1/2, -y, x+1/2'
'-z+1/2, y, -x+1/2'
                                                                    x+2/3,y+1/3,z+1/3
'z+1/2, -y, -x+1/2
                                                                    -y+2/3,x-y+1/3,z+1/3
z+1/2, y, x+1/2
                                                                    -x+y+2/3,-x+1/3,z+1/3
-x+1/2, -y+1/2, -z'
                                                                    y+2/3,x+1/3,-z+1/3
'x+1/2, y+1/2, -z'
'x+1/2, -y+1/2, z'
                                                                    -x+2/3, -x+y+1/3, -z+1/3
'-x+1/2, y+1/2, z'
                                                                    x-y+2/3,-y+1/3,-z+1/3
'-z+1/2, -x+1/2, -y
                                                                    -x+2/3,-y+1/3,-z+1/3
'-z+1/2, x+1/2, y'
                                                                    y+2/3,-x+y+1/3,-z+1/3
z+1/2, x+1/2, -y
z+1/2, -x+1/2, y
                                                                    x-y+2/3,x+1/3,-z+1/3
-y+1/2, -z+1/2, -x
                                                                    -y+2/3,-x+1/3,z+1/3
y+1/2, -z+1/2, x'
                                                                    x+2/3,x-y+1/3,z+1/3
'-y+1/2, z+1/2, x'
y+1/2, z+1/2, -x'
                                                                    -x+y+2/3,y+1/3,z+1/3
'-y+1/2, -x+1/2, z'
'y+1/2, x+1/2, z'
                                                                    loop_
-y+1/2, x+1/2, -z
                                                                     _atom_site_label
'y+1/2, -x+1/2, -z'
-x+1/2, -z+1/2, y
                                                                    atom site type symbol
'x+1/2, -z+1/2, -y
                                                                     _atom_site_fract_x
'x+1/2, z+1/2, y'
                                                                    _atom_site_fract_y
'-x+1/2, z+1/2, -y'
'-z+1/2, -y+1/2, x'
                                                                    atom site fract z
'-z+1/2, y+1/2, -x'
                                                                     atom site occupancy
'z+1/2, -y+1/2, -x'
                                                                    Sn1 Sn 0.00000 0.00000 0.50000 1.00000
'z+1/2, y+1/2, x'
                                                                    Sn2 Sn 0.50000 0.00000 0.50000 1.00000
_cell_length_a
                         4.244(3)
                                                                    H1 H -0.46473 0.46473 0.01893 1.00000
cell length b
                          4.244(3)
                                                                    H2 H
                                                                             0.16805 -0.16805 0.08631 1.00000
cell length c
                         4.244(3)
                                                                    H3 H
                                                                             0.00000 0.00000 -0.24152 1.00000
cell angle alpha
                           90
                                                                    H4 H
                                                                             0.00000 0.00000 0.00000 1.00000
cell_angle_beta
                          90
```

```
cell angle gamma
                                                                     Fd3m-Sn<sub>32</sub>H<sub>120</sub> at 180 GPa (calculations)
cell volume
                          76.44(14)
_cell_formula units Z
                                                                     # CIF file
_cell_measurement reflns used
                                                                     # This file was generated by FINDSYM
cell measurement temperature
                                 293(2)
                                                                     # Harold T. Stokes, Branton J. Campbell, Dorian M. Hatch
cell measurement theta max
                                 14.4550
                                                                     # Brigham Young University, Provo, Utah, USA
cell measurement theta min
                                 4.5250
_shelx_estimated_absorpt_T_max
                                  0.988
                                                                     data findsym-output
                                  0.988
_shelx_estimated_absorpt_T_min
_exptl_absorpt_coefficient_mu
                                24.888
                                                                     symmetry space group name H-M 'F 41/d -3 2/m (origin choice 2)'
exptl absorpt correction T max
                                                                     symmetry Int Tables number 227
exptl absorpt correction T min
exptl absorpt_correction_type
                                                                     _cell_length a
                                                                                      8.57900
exptl absorpt process details
                                                                     _cell_length_b
                                                                                      8.57900
_exptl_absorpt_special_details
_exptl_crystal_colour
                                                                     cell length c
                                                                                      8.57900
                            metallic
                                                                     _cell_angle_alpha 90.00000
_exptl_crystal_colour lustre
                              metallic
_exptl_crystal_density_diffrn
                                                                     cell angle beta 90.00000
                               10.313
                                                                     cell angle gamma 90.00000
exptl crystal density meas
exptl crystal density method
                                                                     cell volume 631.407
                                ?
exptl crystal description
                             irregular
                                                                     loop
exptl crystal F 000
                             200
_exptl_crystal_preparation
                                                                     space group symop operation xyz
exptl crystal size max
                              0.0005
                                                                     x,y,z
                                                                     x,-y+1/4,-z+1/4
exptl crystal size mid
                             0.0005
                                                                     -x+1/4,y,-z+1/4
exptl crystal size min
                             0.0005
exptl transmission factor max
                                                                     -x+1/4,-y+1/4,z
_exptl_transmission_factor_min
                                                                    y,z,x
                                                                    y,-z+1/4,-x+1/4
_diffrn_reflns_av_R_equivalents 0.1356
                                                                     -y+1/4,z,-x+1/4
diffrn reflns av unetI/netI
                              0.0827
                                                                     -y+1/4,-z+1/4,x
diffrn reflns Laue measured fraction full 0.778
diffrn reflns Laue measured fraction max 0.625
                                                                     z,x,y
                                                                     z,-x+1/4,-y+1/4
diffrn reflns limit h max
                                                                     -z+1/4,x,-y+1/4
                               -6
_diffrn_reflns_limit_h_min
__diffrn_reflns_limit_k_max
                               5
                                                                     -z+1/4,-x+1/4,y
diffrn reflns_limit_k_min
                              -5
                                                                     -y,-x,-z
                                                                     -y,x+1/4,z+1/4
                              2
diffrn reflns limit 1 max
                                                                     y+1/4,-x,z+1/4
diffrn reflns limit 1 min
                              -1
diffrn reflns number
                             29
                                                                     y+1/4,x+1/4,-z
                                                                     -x,-z,-y
diffrn reflns point group measured fraction full 0.778
                                                                     -x,z+1/4,y+1/4
diffrn reflns point group measured fraction max 0.625
                                                                     x+1/4,-z,y+1/4
diffrn reflns theta full
                            11.574
                                                                    x+1/4,z+1/4,-y
diffrn reflns theta max
                              14.428
                                                                     -z,-y,-x
_diffrn_reflns_theta_min
                             4.519
                                                                     -z,y+1/4,x+1/4
diffrn ambient temperature
                                293(2)
                                                                     z+1/4,-y,x+1/4
diffrn detector
                         'Pixel detector'
                                                                     z+1/4,y+1/4,-x
diffrn detector area resol mean 5.8140
diffrn detector type
                                                                     -x,-y,-z
                            'Pilatus 1M CdTe'
_diffrn_measured_fraction_theta_full 0.778
                                                                     -x,y+1/4,z+1/4
                                                                     x+1/4,-y,z+1/4
_diffrn_measured_fraction_theta_max 0.625
                                                                     x+1/4,y+1/4,-z
diffrn measurement details
                                                                     -y,-z,-x
                                                                     -y,z+1/4,x+1/4
List of Runs (angles in degrees, time in seconds):
                                                                     y+1/4,-z,x+1/4
 # Type Start End Width t\simexp\sim \w \q \k \f Frames
                                                                     y+1/4,z+1/4,-x
                                                                     -z,-x,-y
                                                                     -z,x+1/4,y+1/4
1 \w -32.00 32.00 0.50 1.00 -- 0.00 0.00 0.00 128
                                                                     z+1/4,-x,y+1/4
                                                                     z+1/4,x+1/4,-y
diffrn measurement device
                                '13IDD @ APS'
diffrn measurement device type 'LH Table'
                                                                    y,x,z
diffrn measurement method
                                                                    y,-x+1/4,-z+1/4
                                 'omega rotation'
                                                                     -y+1/4,x,-z+1/4
diffrn orient matrix type
                                                                     -y+1/4,-x+1/4,z
'CrysAlisPro convention (1999,Acta A55,543-557)'
diffrn orient matrix UB 11
                                -0.0136159167
                                                                    x,z,y
diffrn orient matrix UB 12
                                 -0.0060303500
                                                                     x,-z+1/4,-y+1/4
                                                                     -x+1/4,z,-y+1/4
_diffrn_orient_matrix_UB_13
                                0.0776876667
                                                                     -x+1/4,-z+1/4,y
_diffrn_orient_matrix_UB_21
                                -0.0288921993
_diffrn_orient_matrix_UB_22
                                                                     z,y,x
                                0.0731562500
                                                                     z,-y+1/4,-x+1/4
diffrn orient matrix UB 23
                                0.0012496493
                                                                     -z+1/4,y,-x+1/4
_diffrn_orient_matrix_UB_31
                                -0.0721157857
                                                                     -z+1/4,-y+1/4,x
diffrn orient matrix UB 32
                                -0.0276921000
                                                                     x,y+1/2,z+1/2
diffrn orient matrix UB 33
                                -0.0150944143
                                                                     x,-y+3/4,-z+3/4
diffrn radiation monochromator synchrotron
 diffrn_radiation_probe
                                                                     -x+1/4,y+1/2,-z+3/4
                             x-ray
```

```
diffrn radiation type
                                                                      -x+1/4,-y+3/4,z+1/2
                             synchrotron
_diffrn_radiation_wavelength
                                0.3344
                                                                      y,z+1/2,x+1/2
                          synchrotron
                                                                      y,-z+3/4,-x+3/4
_diffrn_source
_reflns_Friedel coverage
                               0.000
                                                                      -y+1/4,z+1/2,-x+3/4
reflns Friedel fraction full
                                                                      -y+1/4,-z+3/4,x+1/2
reflns Friedel fraction max
                                                                      z,x+1/2,y+1/2
reflns number gt
                            10
                                                                      z,-x+3/4,-y+3/4
_reflns_number_total
                             10
                                                                      -z+1/4,x+1/2,-y+3/4
                                                                      -z+1/4,-x+3/4,y+1/2
_reflns_special_details
                                                                      -y,-x+1/2,-z+1/2
Reflections were merged by SHELXL according to the crystal
                                                                      -y,x+3/4,z+3/4
class for the calculation of statistics and refinement.
                                                                      y+1/4,-x+1/2,z+3/4
                                                                      y+1/4,x+3/4,-z+1/2
 reflns Friedel fraction is defined as the number of unique
                                                                      -x,-z+1/2,-y+1/2
Friedel pairs measured divided by the number that would be
                                                                      -x,z+3/4,y+3/4
possible theoretically, ignoring centric projections and
                                                                      x+1/4,-z+1/2,y+3/4
                                                                      x+1/4,z+3/4,-y+1/2
systematic absences.
                                                                      -z,-y+1/2,-x+1/2
_reflns_threshold_expression
                                'I > 2 \setminus s(I)'
                                                                      -z,y+3/4,x+3/4
                                                                      z+1/4,-y+1/2,x+3/4
computing cell refinement
                                  'CrysAlisPro 1.171.40.69a (Rigaku
OD, 2020)'
                                                                      z+1/4,y+3/4,-x+1/2
computing data collection
                                  'CrysAlisPro 1.171.40.69a (Rigaku
                                                                      -x,-y+1/2,-z+1/2
OD, 2020)'
                                                                      -x,y+3/4,z+3/4
computing data reduction
                                  'CrysAlisPro 1.171.40.69a (Rigaku
                                                                      x+1/4,-y+1/2,z+3/4
                                                                      x+1/4,y+3/4,-z+1/2
OD, 2020)
                                     'Olex2 1.5 (Dolomanov et al.,
                                                                      -y,-z+1/2,-x+1/2
_computing_molecular_graphics
                                                                      -y,z+3/4,x+3/4
2009)
_computing_publication_material
                                     'Olex2 1.5 (Dolomanov et al.,
                                                                      y+1/4,-z+1/2,x+3/4
                                                                      y+1/4,z+3/4,-x+1/2
2009)'
                                                                      -z,-x+1/2,-y+1/2
_computing_structure_refinement
                                      'SHELXL 2014/7 (Sheldrick,
2015)'
                                                                      -z,x+3/4,y+3/4
_computing_structure_solution
                                                                      z+1/4,-x+1/2,y+3/4
refine diff density max
                               1.134
                                                                      z+1/4,x+3/4,-y+1/2
_refine_diff_density min
                              -1.995
                                                                      y,x+1/2,z+1/2
_refine_diff_density_rms
                                                                      y,-x+3/4,-z+3/4
                              0.464
_refine_ls_extinction_coef
                              0.5(6)
                                                                      -y+1/4,x+1/2,-z+3/4
 refine Is extinction expression
                                                                      -y+1/4,-x+3/4,z+1/2
Fc^*^=kFc[1+0.001xFc^2^\l^3^/sin(2\q)]^-1/4^'
                                                                      x,z+1/2,y+1/2
refine ls extinction method
                                'SHELXL-2014/7 (Sheldrick 2014'
                                                                      x,-z+3/4,-y+3/4
refine ls goodness of fit ref
                                1.240
                                                                      -x+1/4,z+1/2,-y+3/4
refine ls hydrogen treatment
                                 undef
                                                                      -x+1/4,-z+3/4,y+1/2
_refine_ls_matrix_type
                                                                      z,y+1/2,x+1/2
                             full
_refine_ls_number_parameters
                                                                      z,-y+3/4,-x+3/4
                               10
                                                                      -z+1/4,y+1/2,-x+3/4
_refine_ls_number_reflns
_refine_ls_number_restraints
                                                                      -z+1/4,-y+3/4,x+1/2
                               0
refine ls R factor all
                             0.0475
                                                                      x+1/2,y,z+1/2
                                                                      x+1/2,-y+1/4,-z+3/4
_refine_ls_R_factor_gt
                             0.0475
_refine_ls_restrained_S_all
                              1.240
                                                                      -x+3/4,y,-z+3/4
_refine_ls_shift/su_max
                              0.000
                                                                      -x+3/4,-y+1/4,z+1/2
refine ls shift/su mean
                              0.000
                                                                      y+1/2,z,x+1/2
refine ls structure factor coef Fsqd
                                                                      y+1/2,-z+1/4,-x+3/4
                                                                      -y+3/4,z,-x+3/4
refine ls weighting details
w=1/[s^2(Fo^2)+22.1894P] where P=(Fo^2+2Fc^2)/3'
                                                                      -y+3/4,-z+1/4,x+1/2
_refine_ls_weighting_scheme
                                 calc
                                                                      z+1/2,x,y+1/2
refine_ls_wR_factor_gt
                               0.0960
                                                                      z+1/2,-x+1/4,-y+3/4
refine_ls_wR_factor_ref
                               0.0960
                                                                      -z+3/4,x,-y+3/4
refine special details
                                                                      -z+3/4,-x+1/4,y+1/2
                                                                      -y+1/2,-x,-z+1/2
olex2 refinement description
                                                                      -y+1/2,x+1/4,z+3/4
                                                                      y+3/4,-x,z+3/4
                                                                      y+3/4,x+1/4,-z+1/2
atom sites solution hydrogens
atom sites solution primary
                                                                      -x+1/2,-z,-y+1/2
 atom sites solution secondary
                                                                      -x+1/2,z+1/4,y+3/4
                                                                      x+3/4,-z,y+3/4
loop
 atom site label
                                                                      x+3/4,z+1/4,-y+1/2
 _atom_site_type_symbol
                                                                      -z+1/2,-y,-x+1/2
                                                                      -z+1/2,y+1/4,x+3/4
 _atom_site_fract_x
 _atom_site_fract_y
                                                                      z+3/4,-y,x+3/4
 atom site fract z
                                                                      z+3/4,y+1/4,-x+1/2
                                                                      -x+1/2,-y,-z+1/2
 _atom_site_U_iso_or_equiv
                                                                      -x+1/2,y+1/4,z+3/4
 atom site adp type
                                                                      x+3/4,-y,z+3/4
 atom site occupancy
                                                                      x+3/4,y+1/4,-z+1/2
 _atom_site_site_symmetry_order
  atom_site_calc_flag
                                                                      -y+1/2,-z,-x+1/2
```

```
-y+1/2,z+1/4,x+3/4
 atom site refinement flags posn
 atom site refinement flags adp
                                                                     y+3/4,-z,x+3/4
                                                                     y+3/4,z+1/4,-x+1/2
 _atom_site_refinement_flags_occupancy
 _atom_site_disorder assembly
                                                                     -z+1/2,-x,-y+1/2
  atom site disorder group
                                                                     -z+1/2,x+1/4,y+3/4
Sn01 Sn 0.0000 0.0000 0.0000 0.024(6) Uani 1 48 d S T P . .
                                                                     z+3/4,-x,y+3/4
                                                                     z+3/4,x+1/4,-y+1/2
                                                                     y+1/2,x,z+1/2
 _atom_site_aniso_label
                                                                     y+1/2,-x+1/4,-z+3/4
 _atom_site_aniso_U_11
                                                                     -y+3/4,x,-z+3/4
 atom site aniso U 22
                                                                     -y+3/4,-x+1/4,z+1/2
 atom site aniso U 33
                                                                     x+1/2,z,y+1/2
 _atom_site_aniso_U 23
                                                                     x+1/2,-z+1/4,-y+3/4
 _atom_site_aniso_U 13
                                                                     -x+3/4,z,-y+3/4
 atom site aniso U 12
                                                                     -x+3/4,-z+1/4,y+1/2
Sn01 0.024(6) 0.024(6) 0.024(6) 0.000 0.000 0.000
                                                                     z+1/2,y,x+1/2
                                                                     z+1/2,-y+1/4,-x+3/4
_geom_special_details
                                                                     -z+3/4,y,-x+3/4
                                                                     -z+3/4,-y+1/4,x+1/2
All esds (except the esd in the dihedral angle between two l.s. planes)
                                                                     x+1/2,y+1/2,z
are estimated using the full covariance matrix. The cell esds are taken
                                                                     x+1/2,-y+3/4,-z+1/4
                                                                     -x+3/4,y+1/2,-z+1/4
into account individually in the estimation of esds in distances, angles
and torsion angles; correlations between esds in cell parameters are
                                                                     -x+3/4,-y+3/4,z
                                                                     y+1/2,z+1/2,x
                                                                     y+1/2,-z+3/4,-x+1/4
used when they are defined by crystal symmetry. An approximate
                                                                     -y+3/4,z+1/2,-x+1/4
(isotropic)
treatment of cell esds is used for estimating esds involving l.s. planes.
                                                                     -y+3/4,-z+3/4,x
                                                                     z+1/2,x+1/2,y
                                                                     z+1/2,-x+3/4,-y+1/4
loop_
 _geom_bond_atom_site label 1
                                                                     -z+3/4,x+1/2,-y+1/4
 _geom_bond_atom_site_label_2
                                                                     -z+3/4,-x+3/4,y
 _geom_bond distance
                                                                     -y+1/2,-x+1/2,-z
 _geom_bond_site_symmetry 2
                                                                     -y+1/2,x+3/4,z+1/4
 _geom_bond_publ_flag
                                                                     y+3/4,-x+1/2,z+1/4
Sn01 Sn01 3.0010(18) 73 ?
                                                                     y+3/4,x+3/4,-z
Sn01 Sn01 3.0010(18) 49 554?
                                                                     -x+1/2,-z+1/2,-y
Sn01 Sn01 3.0010(18) 25 554?
                                                                     -x+1/2,z+3/4,y+1/4
Sn01 Sn01 3.0010(18) 25_544 ?
                                                                     x+3/4,-z+1/2,y+1/4
Sn01 Sn01 3.0010(18) 73 545?
                                                                     x+3/4,z+3/4,-v
Sn01 Sn01 3.0010(18) 73 445?
                                                                     -z+1/2,-y+1/2,-x
                                                                     -z+1/2,y+3/4,x+1/4
Sn01 Sn01 3.0010(18) 49 455?
Sn01 Sn01 3.0010(18) 49 ?
                                                                     z+3/4,-y+1/2,x+1/4
Sn01 Sn01 3.0010(18) 25 545 ?
                                                                     z+3/4,y+3/4,-x
                                                                     -x+1/2,-y+1/2,-z
Sn01 Sn01 3.0010(18) 25 ?
                                                                     -x+1/2,y+3/4,z+1/4
Sn01 Sn01 3.0010(18) 73 455 ?
Sn01 Sn01 3.0010(18) 49 454 ?
                                                                     x+3/4,-y+1/2,z+1/4
                                                                     x+3/4,y+3/4,-z
                                                                     -y+1/2,-z+1/2,-x
loop_
 _geom_angle_atom_site_label 1
                                                                     -y+1/2,z+3/4,x+1/4
 _geom_angle_atom_site_label 2
                                                                     y+3/4,-z+1/2,x+1/4
                                                                     y+3/4,z+3/4,-x
 _geom_angle_atom_site_label_3
 _geom_angle
                                                                     -z+1/2,-x+1/2,-y
 _geom_angle_site_symmetry_1
                                                                     -z+1/2,x+3/4,y+1/4
                                                                     z+3/4,-x+1/2,y+1/4
 _geom_angle_site_symmetry_3
 _geom_angle_publ_flag
                                                                     z+3/4,x+3/4,-v
Sn01 Sn01 Sn01 120.0 73 25 544 ?
                                                                     y+1/2,x+1/2,z
Sn01 Sn01 Sn01 120.0 25 545 73 455 ?
                                                                     y+1/2,-x+3/4,-z+1/4
Sn01 Sn01 Sn01 60.0 49 73 545 ?
                                                                     -y+3/4,x+1/2,-z+1/4
Sn01 Sn01 Sn01 180.0 73 73 445 ?
                                                                     -y+3/4,-x+3/4,z
Sn01 Sn01 Sn01 90.0 25 25 545 ?
                                                                     x+1/2,z+1/2,y
Sn01 Sn01 Sn01 60.0 25 544 73 445 ?
                                                                     x+1/2,-z+3/4,-y+1/4
Sn01 Sn01 Sn01 120.0 25 544 73 455 ?
                                                                     -x+3/4,z+1/2,-y+1/4
Sn01 Sn01 Sn01 60.0 73 49 ?
                                                                     -x+3/4,-z+3/4,y
Sn01 Sn01 Sn01 120.0 73 25_545 ?
                                                                     z+1/2,y+1/2,x
Sn01 Sn01 Sn01 120.0 25 544 49 ?
                                                                     z+1/2,-y+3/4,-x+1/4
Sn01 Sn01 Sn01 120.0 49 554 25 545?
                                                                     -z+3/4,y+1/2,-x+1/4
Sn01 Sn01 Sn01 120.0 73_445 49 ?
                                                                     -z+3/4,-y+3/4,x
Sn01 Sn01 Sn01 120.0 49 455 73 545 ?
Sn01 Sn01 Sn01 60.0 73 25 ?
                                                                     loop_
Sn01 Sn01 Sn01 60.0 49_454 73_455 ?
                                                                     _atom_site_label
Sn01 Sn01 Sn01 180.0 25 544 25 ?
                                                                     atom site type symbol
Sn01 Sn01 Sn01 60.0 25 554 49 554 ?
                                                                     atom site fract x
Sn01 Sn01 Sn01 120.0 73 445 25 ?
                                                                     atom site fract y
Sn01 Sn01 Sn01 60.0 73 445 25 545 ?
                                                                      atom_site_fract_z
```

```
Sn01 Sn01 Sn01 60.0 49 25 ?
                                                                  atom site occupancy
                                                                 Sn1 Sn 0.50000 0.50000 0.50000 1.00000
Sn01 Sn01 Sn01 180.0 25 554 25 545?
Sn01 Sn01 Sn01 120.0 73 49 454?
                                                                 Sn2 Sn 0.00000 0.00000 0.00000 1.00000
Sn01 Sn01 Sn01 60.0 25 544 73 545 ?
                                                                 H1 H -0.12413 0.12500 0.12500 1.00000
Sn01 Sn01 Sn01 60.0 25 544 49 454 ?
                                                                 H2 H 0.28368 0.28368 0.28368 1.00000
Sn01 Sn01 Sn01 120.0 49 454 73 545 ?
                                                                 НЗ Н 0.22628 0.22628 0.22628 1.00000
Sn01 Sn01 Sn01 60.0 73 445 49 454 ?
                                                                 H4 H 0.12500 0.12500 0.12500 1.00000
Sn01 Sn01 Sn01 60.0 25 545 73 545 ?
Sn01 Sn01 Sn01 180.0 49 49 454?
Sn01 Sn01 Sn01 120.0 49 73 455 ?
Sn01 Sn01 Sn01 120.0 25 49 454?
Sn01 Sn01 Sn01 60.0 49 455 73 455 ?
Sn01 Sn01 Sn01 60.0 73 25 554?
Sn01 Sn01 Sn01 90.0 49 454 49 554?
Sn01 Sn01 Sn01 90.0 25 544 25 554 ?
Sn01 Sn01 Sn01 180.0 49 455 49 554?
Sn01 Sn01 Sn01 120.0 73 445 25 554 ?
Sn01 Sn01 Sn01 90.0 25 544 25 545 ?
Sn01 Sn01 Sn01 120.0 49 25 554?
Sn01 Sn01 Sn01 60.0 49 25 545?
Sn01 Sn01 Sn01 90.0 25 25 554 ?
Sn01 Sn01 Sn01 120.0 49 454 25 545 ?
Sn01 Sn01 Sn01 60.0 49 454 25 554 ?
Sn01 Sn01 Sn01 60.0 49 455 25 545 ?
Sn01 Sn01 Sn01 120.0 7\overline{3} 49 45\overline{5} ?
Sn01 Sn01 Sn01 90.0 73 73 545 ?
Sn01 Sn01 Sn01 120.0 25 544 49 455?
Sn01 Sn01 Sn01 90.0 73_445 73_545 ?
Sn01 Sn01 Sn01 60.0 73 445 49 455 ?
Sn01 Sn01 Sn01 120.0 25 73 545 ?
Sn01 Sn01 Sn01 90.0 49 49 455?
Sn01 Sn01 Sn01 120.0 25 554 73 545 ?
Sn01 Sn01 Sn01 60.0 25 49 455 ?
Sn01 Sn01 Sn01 60.0 49 554 73 545 ?
Sn01 Sn01 Sn01 90.0 49 454 49 455 ?
Sn01 Sn01 Sn01 90.0 73 73 455?
Sn01 Sn01 Sn01 120.0 25 554 49 455 ?
Sn01 Sn01 Sn01 90.0 73 445 73 455 ?
Sn01 Sn01 Sn01 60.0 73 49 554?
Sn01 Sn01 Sn01 60.0 25 73 455 ?
Sn01 Sn01 Sn01 60.0 25 544 49 554?
Sn01 Sn01 Sn01 60.0 25 554 73 455 ?
Sn01 Sn01 Sn01 120.0 73 445 49 554 ?
Sn01 Sn01 Sn01 120.0 49 554 73 455 ?
Sn01 Sn01 Sn01 90.0 49 49 554?
Sn01 Sn01 Sn01 180.0 73 545 73 455 ?
Sn01 Sn01 Sn01 120.0 25 49 554?
_shelx_res_file
  cf snh4.res created by SHELXL-2014/7
TITL snh p02 q3 pos130
CELL 0.3344 4.244 4.244 4.244 90 90 90
ZERR 4 0.002599 0.002599 0.002599 0 0 0
LATT 4
SYMM -X,-Y,+Z
SYMM -X.+Y.-Z
SYMM + X, -Y, -Z
SYMM + Z, +X, +Y
SYMM + Z, -X, -Y
SYMM -Z,-X,+Y
SYMM -Z,+X,-Y
SYMM +Y,+Z,+X
SYMM -Y,+Z,-X
SYMM + Y, -Z, -X
SYMM -Y,-Z,+X
SYMM + Y, +X, -Z
SYMM -Y,-X,-Z
SYMM +Y,-X,+Z
SYMM - Y, +X, +Z
SYMM + X, +Z, -Y
SYMM -X,+Z,+Y
SYMM -X,-Z,-Y
```

```
SYMM + X, -Z, +Y
SYMM +Z,+Y,-X
SYMM + Z, -Y, +X
SYMM -Z,+Y,+X
SYMM -Z,-Y,-X
SFAC Sn
DISP Sn -0.6925 2.405 4756.1985
UNIT 4
L.S. 1000
PLAN 5
SIZE 0.0005 0.0005 0.0005
CONF
MORE -1
fmap 2 53
ACTA
REM <olex2.extras>
REM < HklSrc "%.\cF_SnH4.hkl">
REM </olex2.extras>
WGHT 0.000000 22.189402
EXTI 0.541500
FVAR
       1.01538
SN01 1 0.000000 0.000000
                               0.000000
                                         10.02083 0.02443
0.02443 =
    0.02443 0.00000 0.00000 0.00000
HKLF 4
REM \ snh\_p02\_q3\_pos130
REM R1 = 0.0475 for
                      10 \text{ Fo} > 4 \text{sig}(\text{Fo}) and 0.0475 \text{ for all}
data
REM
       3 parameters refined using 0 restraints
END
WGHT 0.0000 19.9852
REM Highest difference peak 1.134, deepest hole -1.995, 1-sigma
level 0.464
Q1 1 0.2500 0.2500 -0.1231 10.25000 0.05 1.13
Q2 1 0.0000 0.3032 0.0000 10.12500 0.05 0.94
Q3 1 0.0000 0.0000 0.0773 10.12500 0.05
                                          0.91
Q4 1 0.1739 0.0000 0.0000 10.12500 0.05 0.90
Q5 1 0.0000 -0.3415 0.1585 10.25000 0.05 0.72
shelx res checksum
                           69794
_shelx_hkl_file
-2 0 010079.50 48.90 1
 0 -2 012715.90 83.54 1
 -2 -2 0 7816.28 71.28 1
 1 -3 1 6288.93 151.82 1
 -1 3 1 5994.86 153.40 1
 -3 1 -1 7997.15 113.20 1
 -1 3 -1 7219.69 163.26 1
 -3 3 1 3471.32 189.81 1
 3 -3 1 3498.64 184.45 1
 3 3 1 2777.11 98.18 1
 -3 3 -1 4243.44 191.87 1
 0 -4 0 3709.52 173.03 1
 0 4 0 3934.57 176.98 1
 4 -2 2 2634.75 170.81
 4 0 2 3645.09 107.95 1
 -2 4 0 3888.53 210.43 1
 2 -4 0 3751.22 208.44 1
 2 4 2 2135.76 161.07 1
 4 2 2 751.01 68.82 1
 5 -1 1 970.27 147.15 1
 -1 -5 -1 1070.62 209.66 1
 1 5 1 2075.23 203.40 1
 -1 -5 1 1685.69 208.09 1
 -5 1 -1 2010.98 150.14 1
 5 -3 1 940.45 232.90 1
 -3 -5 -1 438.57 178.09 1
```

```
3 5 1 1245.79 187.15 1
-5 3 -1 1368.40 233.43 1
-6 2 0 672.27 208.70 1
0 0 0 0.00 0.00 0
;
_shelx_hkl_checksum 70650
_olex2_submission_special_instructions 'No special instructions were received'
_oxdiff_exptl_absorpt_empirical_details
;
Empirical correction (ABSPACK) includes:
;
_oxdiff_exptl_absorpt_empirical_full_max 1.000
_oxdiff_exptl_absorpt_empirical_full_min 1.000
```

Table S7. Experimental unit cell parameters of proposed distorted $Im\overline{3}m$ (Z = 2) phase and $P6_3/mmc$ -Sn (Z = 2) obtained from the exteriments at PETRA-III in 2020 at different pressures (DAC M2).

Experiment and pressure	a, Å	b, Å	c, Å	<i>V</i> , Å ³	a, Å	c, Å	V, Å ³
P02 (h1), 180 GPa	2.895	2.895	2.895	24.26	2.633	4.581	27.51
P02 (h3), 185 GPa	2.885	2.935	2.845	24.09	2.634	4.595	27.61
P03, 190-196 GPa	2.885 2.885	2.865 2.925	2.895 2.835	23.93 23.92	2.716	4.093	26.15
P04, 201-208 GPa	2.863 2.870	2.863 2.870	2.863 2.870	23.47 23.64	2.634	4.435	26.65
P05, 208-210 GPa	2.855	2.905	2.825	23.43	2.621	4.415	26.32

Table S8. Calculated unit cell parameters of $Im\bar{3}m$ -Sn (Z=2) and $Fd\bar{3}m$ -Sn₈H₃₀ (Z = 8 or 32).

Pressure, GPa	a, Å (Sn)	$V, Å^3 (Sn)$	a, Å (Z=8)	$V, Å^3 (Z=8)$	$V, Å^3 (Z=32)$	V, Å ³ /Sn
160	3.0503	28.38	5.4737	164.0	656.0	20.50
180	3.0195	27.53	5.4115	158.47	633.88	19.81
200	2.9922	26.79	5.3556	153.61	614.44	19.20
210	2.9799	26.46	5.3294	151.37	605.48	18.92
220	2.9674	26.13	5.3044	149.25	597.0	18.65
230	2.955	25.82	1	-	-	-
240	2.944	25.52	1	-	-	-

Table S9. Experimental unit cell parameters of C2/m-SnH₁₄ (Z=2) at different pressures, the experiment was done at PETRA III in 2020. "h1" denotes the first laser heating, "h3" – the third laser heating.

Experiment and pressure	a, Å	b, Å	c, Å	β,°	V, Å ³	V, Å ³ /Sn
DAC D2, 193 GPa	7.450	2.870	3.860	120.0	71.6	35.80
DAC M2, P02 (h1), 180 GPa	7.756	2.871	3.797	118.34	74.42	37.21
DAC M2, P02 (h3), 185 GPa	7.529	2.888	3.806	118.34	72.87	36.43
DAC M2, P03, 190-196 GPa	7.542	2.876	3.815	118.74	72.57	36.28
DAC M2, P04, 201-208 GPa	7.495	2.863	3.813	117.21	72.79	36.39
DAC M2, P05, 208-210 GPa	7.482	2.854	3.790	117.74	71.66	35.83

Table S10. Calculated unit cell parameters of C2/m-SnH₁₄ at different pressures.

Pressure, GPa	a, Å	b, Å	c, Å	$(180 - \beta)$, °	V, Å ³	V, Å ³ /Sn
160	7.628	2.940	3.907	61.56	77.07	38.53
180	7.534	2.901	3.866	61.38	74.19	37.09
200	7.445	2.866	3.828	61.27	71.66	35.83
210	7.406	2.850	3.812	61.17	70.51	35.25
220	7.368	2.834	3.796	61.11	69.43	34.71
230	7.334	2.820	3.779	61.05	68.41	34.21
240	7.297	2.805	3.766	61.00	67.44	33.72

Table S11. Calculated unit cell parameters of cubic SnH_2 (prototype is $Fm\overline{3}m$ -YH₂) and SnH_3 (prototype is $Fm\overline{3}m$ -YH₃).

Риоссина СРо	Fm	-3m-Sn ₄ H ₁₂ (Sn	H ₃)	$Fm-3m-Sn_4H_8(SnH_2)$			
Pressure, GPa	a, Å (Z=4)	$V, Å^3 (Z=4)$	V, Å ³ /Sn	a, Å (Z=4)	$V, Å^3 (Z=4)$	V, Å ³ /Sn	
160	4.232	75.79	18.95	4.188	73.43	18.36	
180	4.186	73.34	18.33	4.139	70.95	17.74	
200	4.146	71.26	17.81	4.098	68.82	17.20	
210	4.126	70.26	17.56	4.078	67.81	16.95	
220	4.107	69.26	17.32	4.058	66.85	16.71	

Table S12. Calculated unit cell parameters of $Fm\overline{3}m$ -SnH₅, $Fm\overline{3}m$ -SnH₆, $Fm\overline{3}m$ -SnH₇ (prototype is YMg₇), $Fm\overline{3}m$ -SnH₈ (prototype is UH₈), $F\overline{4}3m$ -SnH₉ (prototype is PrH₉) and $Fm\overline{3}m$ -SnH₁₀ (prototype is LaH₁₀).

Pressure, GPa	V, Å ³ /Sn (SnH ₅)	V, Å ³ /Sn (SnH ₆)	V, Å ³ /Sn (SnH ₇)	V, Å ³ /Sn (SnH ₈)	V, Å ³ /Sn (SnH ₉)	V, Å ³ /Sn (SnH ₁₀)
180	21.50	26.54	27.00	26.32	-	-
200	20.86	25.68	26.17	25.56	26.93	28.52
210	20.56	25.38	25.82	25.20	26.54	28.10
220	20.30	25.01	25.45	24.84	26.17	27.70
230	-	-	-	-	25.80	27.32
240	-	-	-	-	25.47	26.94

4. Raman spectra

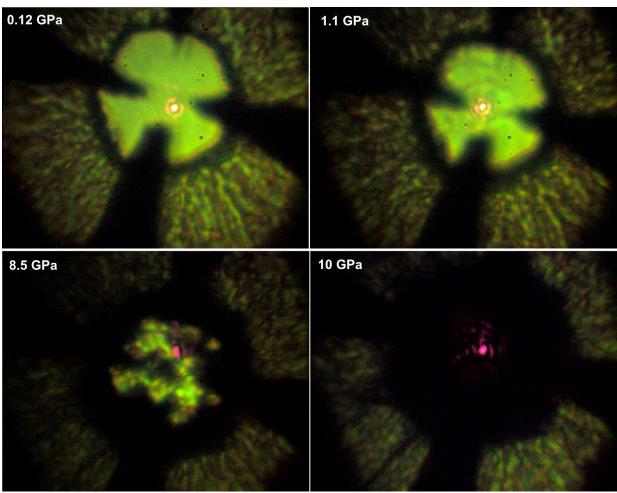


Figure S7. Metallization of molecular stannane compressed in a diamond anvil cell to 10 GPa. A cryogenic loading of the DAC was used.

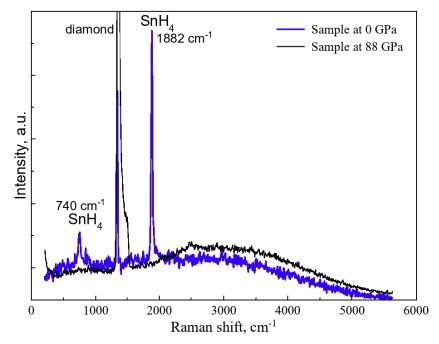


Figure S8. Raman spectrum of stannane (SnH₄) immediately after loading into the diamond cell (0 GPa, blue line) and after metallization (at 88 GPa, black line). The wavelength of the exciting laser is 633 nm.

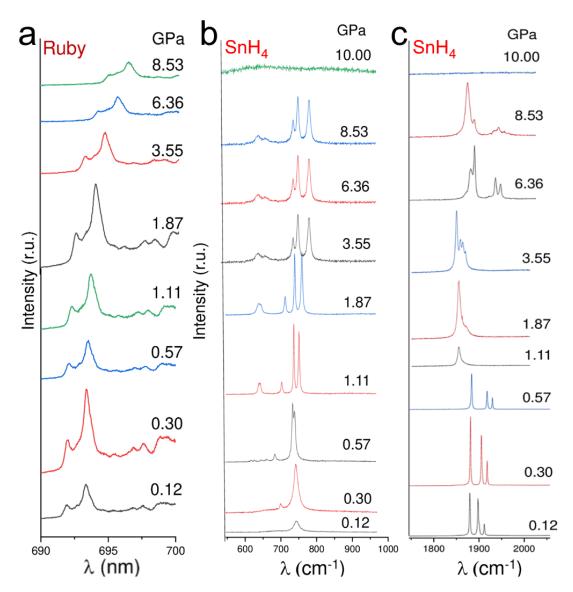


Figure S9. Raman spectra of stannane below 10 GPa measured at 157-164 K. (a) The ruby fluorescence peak and its changes with pressure. (b) Raman spectra of SnH₄ in 600-1000 cm⁻¹ range at different pressures. There are signs of phase transitions in SnH₄ as the pressure increases. (c) Raman spectra of SnH₄ in 1700-2100 cm⁻¹ range at different pressures. Above 10 GPa, the Raman peaks of stannane disappear. The wavelength of the exciting laser is 633 nm.

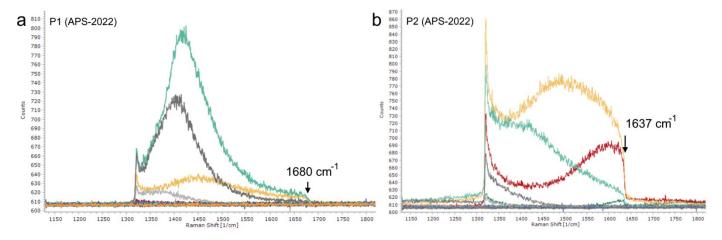


Figure S10. Raman spectra of the diamond anvils in the region of C-C vibrations, obtained at APS-2022. Different curves correspond to different points on the diamond culet.

5. Electron and phonon band structures of tin hydrides

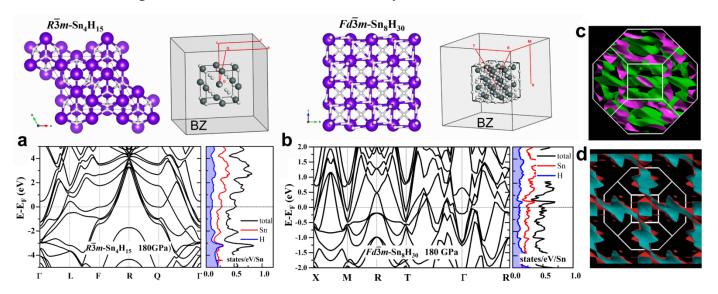


Figure S11. Crystal and electron band structures of (a) $R\bar{3}m$ -Sn₁₂H₄₅ (Sn₄H₁₅) and (b) $Fd\bar{3}m$ -Sn₈H₃₀ calculated at 180 GPa (PAW PBE). (c, d) Sections of the Fermi surface of $Fd\bar{3}m$ -Sn₈H₃₀ showing its open character (XCrySDen). Bands correspond to $E_{min} = 15.39$ eV, $E_{max} = 18.07$ eV (c) and $E_{min} = 16.36$ eV, $E_{max} = 18.11$ eV (d) intervals.

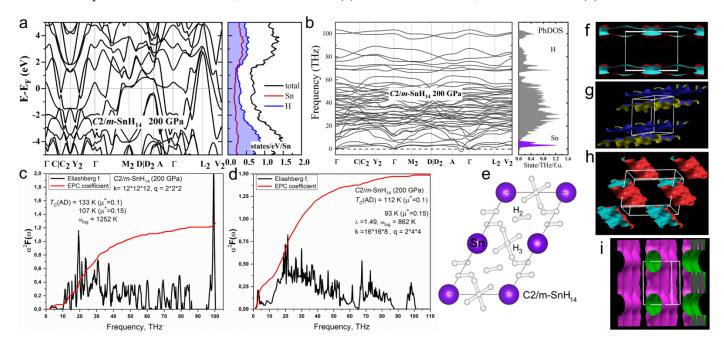


Figure S12. Electron (a), phonon (b) band structures and crystal structure (e), as well as Eliashberg functions (c, d) of C2/m-SnH₁₄ at 200 GPa. Red lines in (c, d) correspond the dependence of the electron-phonon coupling coefficient on the frequency. (f-i) Sections of the Fermi surface of C2/m-SnH₁₄ at 200 GPa showing its open character (XCrySDen).

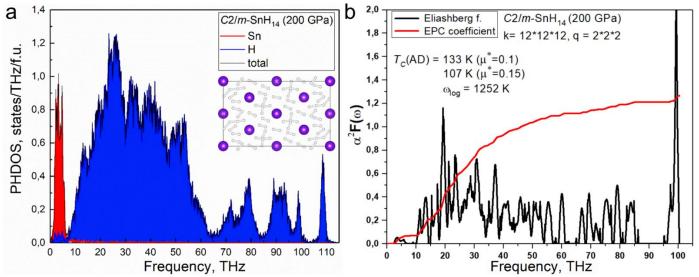


Figure S13. (a) Anharmonic density of phonon states at 200 GPa and 300 K obtained using molecular dynamics with MTP potentials, and (b) harmonic Eliashberg function with parameters of superconductivity of C2/m-SnH₁₄.

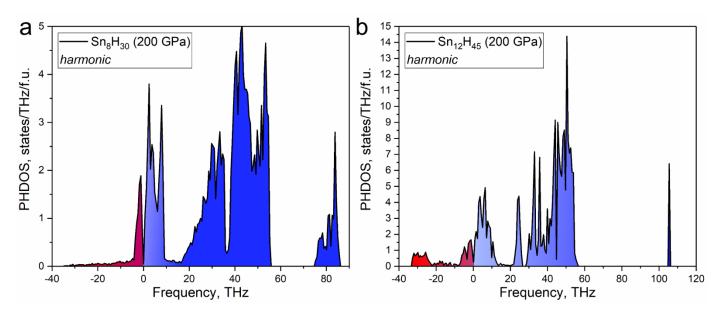


Figure S14. Harmonic density of phonon states of (a) $Fd\overline{3}m$ -Sn₈H₃₀ (f.u. = Sn₈H₃₀) and (b) $R\overline{3}m$ -Sn₁₂H₄₅ (f.u. = Sn₁₂H₄₅) at 200 GPa and 0 K obtained using VASP ¹⁰⁻¹² and Phonopy ^{13,14} codes. The imaginary part is marked in red.

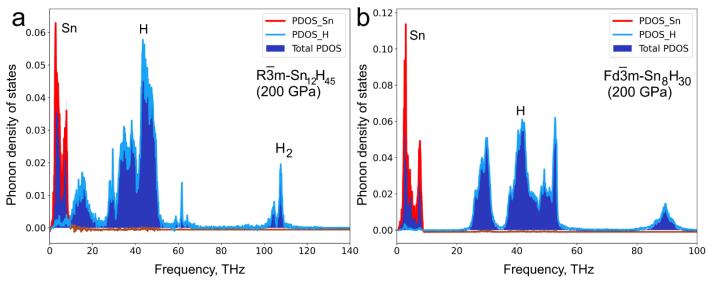


Figure S15. Anharmonic density of phonon states (integral of PDOS is normalized to 1, THz⁻¹) of (a) $R\overline{3}m$ -Sn₁₂H₄₅ and (b) $Fd\overline{3}m$ -Sn₈H₃₀ at 200 GPa and 300 K obtained using molecular dynamics with MTP potentials.

6. Transport and superconducting properties

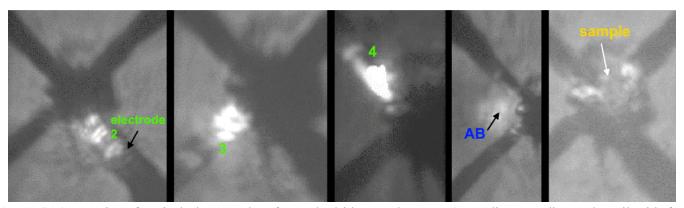


Figure S16. A series of optical photographs of a Sn hydride sample on a 50-µm diameter diamond anvil with four sputtered electrical contacts. Arrows and numbers show electrodes, ammonia borane (AB), and the sample.

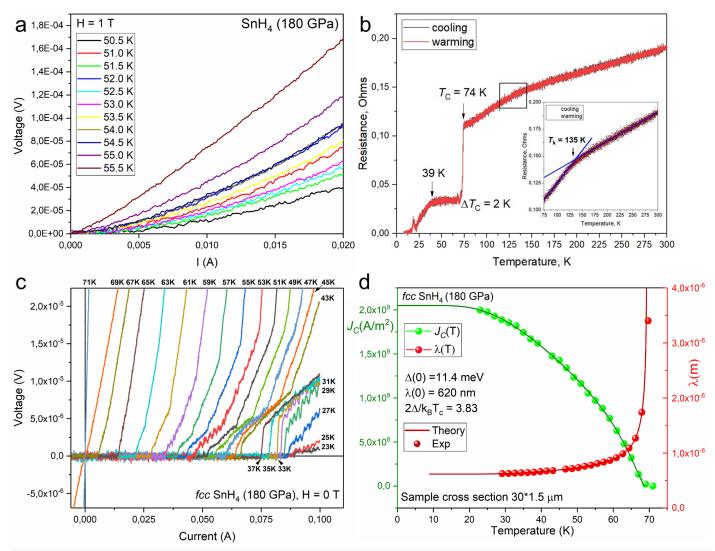


Figure S17. (a) Voltage-current (V-I) characteristic of the cubic SnH₄ sample at 180 GPa in a 1T magnetic field (H) in the temperature range of 50.5 - 55.5 K. The moment of transition to the superconducting state is weakly expressed probably due to heating of the sample (there is a quadratic ∼T² component in V(I)). (b) Temperature dependence of the electrical resistance in a multiphase Sn hydride sample at 190 GPa (3rd laser heating). The inset shows a previously discovered anomaly (kink) at 135 K. Signs of a second, probable, superconducting transition are observed at ∼39 K. (c) Voltage-current (V-I) characteristic of the cubic SnH₄ sample at 180 GPa in the absence of magnetic field in the temperature range of 23 - 71 K. (d) Temperature dependence of critical current density (green balls) and penetration depth (red balls) and fitting curves based on the results of Talantsev et al. ^{26,27}.

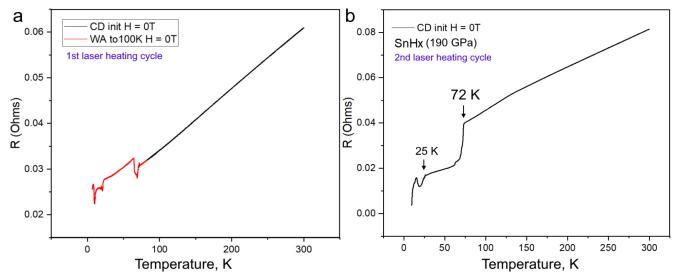


Figure S18. Temperature dependence of the electrical resistance for insufficiently heated Sn samples at 190 GPa. (a) The first cycle of laser heating. Only a local resistance anomaly is observed in the region of the expected superconducting transition (70 - 75 K). (b) The second cycle of laser heating. Due to an increase in the concentration of superconducting phase in the sample, a partial resistive transition at 72 K was observed. The third laser heating cycle results in the curve shown in Figure 17b.

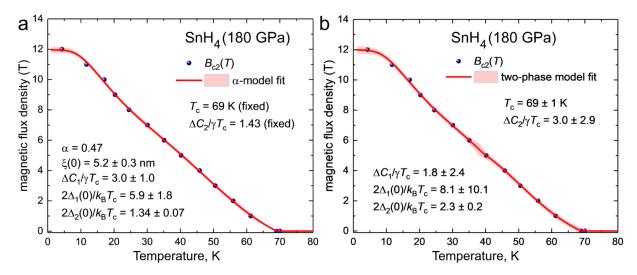


Figure S19. Possible explanation of the quasilinear dependence of the upper magnetic field on temperature $B_{C2}(T)$ for cubic SnH₄ using two-gap models: (a) α-model, (b) two-phase model. The critical temperature $T_C = 69$ K is taken at the first point where R(T) < 0. The analysis was carried out by Dr. Evgueni Talantsev (M.N. Mikheev Institute of Metal Physics, Ural Branch of RAS).

Estimation of the upper critical magnetic field of $Fd\overline{3}m$ -Sn₈H₃₀ in the clean limit by a simplified model for hydrides, suggested in Ref. ⁴¹, gives:

$$B_{C2}^{cl}(0) = 2.45 \times 10^{-4} T_C^2 (1 + \lambda)^2,$$
 (S7)

where $T_C = 72$ K, and λ is the electron-phonon interaction parameter which varies from 1.24 (harmonic approximation) to 2.98 (anharmonic approximation). Depending on the λ value, Eq. (4) gives $B_{C2}(0) = 6.4 - 20.3$ T, which is in acceptable agreement with the experimental data (14-16 T). From eq. (S7), considering the anomalously linear dependence R(T), it follows that the value of the electron-phonon interaction parameter in Sn tetrahydride is quite large ($\lambda \sim 2.5$).

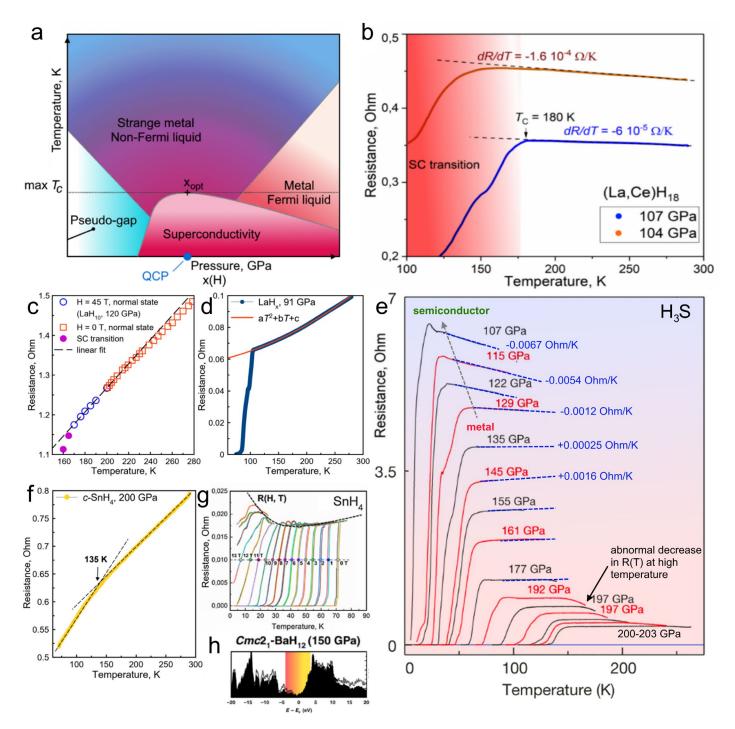


Figure S20. Examples of anomalous behavior of superhydrides in the normal resistivity state and their hypothetical phase diagram. (a) Qualitative P-T phase diagram of compressed hydrides, constructed by analogy with cuprates. Similar to doping level in cuprates, pressure (P) plays the same role in hydrides. (b) Anomalous linear decrease in electrical resistance ($d\rho/dT < 0$) with increasing temperature in (La, Ce)H₉ ⁴². (c) Anomalous temperature dependence (close to T-linear) of electrical resistance in LaH₁₀, observed at 120 GPa after suppression of the superconducting state by a magnetic field of 45 T ⁴³. (d) The Fermi liquid behavior of R(T) in LaH_x at 91 GPa. The electrical resistance can be approximated by a quadratic function ⁴². (e) Gradual transition of sulfur hydride (H₃S) from a metallic (non-Fermi liquid) phase to a semiconducting pseudo-gap phase (below 135 GPa) with the inversion of sign of the temperature coefficient of resistance and the disappearance of superconductivity below 107 GPa ⁴⁴. (f) Anomalous reproducible kink of R(T) in fcc SnH₄ which cannot be explained in terms of the Fermi liquid model. (g) Growth of electrical resistance of cubic SnH₄ at low temperatures after suppression of superconductivity by magnetic field. This is a probable manifestation of pseudo-gap phase. (h) Pronounced pseudo-gap in the electronic structure of a superconducting molecular $Cmc2_1$ -BaH₁₂ at 150 GPa ⁴⁵.

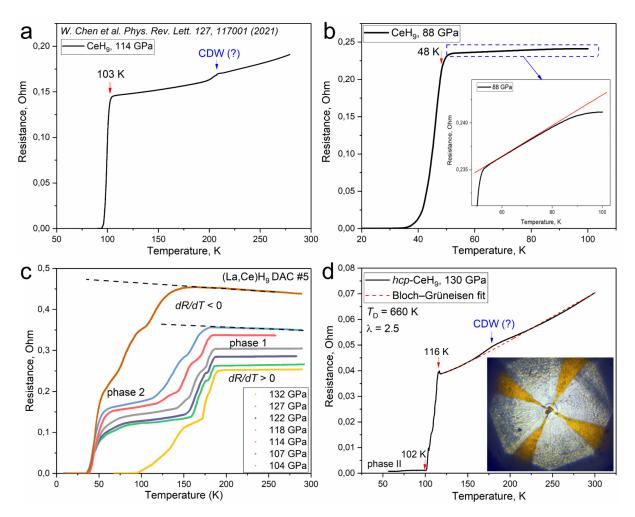


Figure S21. Examples of anomalous behavior of electrical resistance in samples of cerium and lanthanum-cerium hydrides. (a) Temperature dependence R(T) in CeH₉ at 114 GPa, (b) the same dependence at 88 GPa ⁴⁶. In both cases, R(T) cannot be interpolated using the Bloch–Grüneisen formula ^{47,48}. (c) Reversal of the sign of the temperature coefficient of electrical resistance during decompression of (La,Ce)H₉ ⁴². A similar effect is observed in *bcc* H₃S with decreasing pressure ⁴⁴. (d) Reproducible anomaly of the R(T) dependence in $P6_3/mmc$ -CeH₉. This experiment was carried out in Moscow (IC RAS) in 2022. CDW means the charge density wave, which is one of the possible reasons of such anomalies in CeH₉ at high pressure.

Table S13. Parameters of the normal resistivity state of the cubic SnH₄ found in the study of the magnetoresistance. The mobility of electrons and their relaxation time were calculated from the quadratic part of the $\rho(B)$ dependence and, in order of magnitude, they correspond to the parameters of metals (e.g., Sr, Ba, Pb...) ⁴⁹.

Temperature, K	Crit. magnetic field (B_{cr}), T	Cyclotron time (τ_c) , s^{-1}	Electron mobility $(\rho = \mu^2 B^2)$, $m^2/s \times V$	Electron relaxation time, $(\tau = \mu \times m_e/e), s^{-1}$
75*	5	1.1e-12	0.033	1.9e-13
80	6	9.5e-13	0.035	2e-13
100*	7.5	7.6e-13	0.022	1.25e-13
145.5	12	4.7e-13	0.017	9.45e-14
216	14	4e-13	0.015	8.53e-14

^{*}PPMS measurements

It should also be noted that the linear behavior of the magnetoresistance (MR) is also typical for polycrystalline metals with an open Fermi surface, for example, for Li, Cu, Ag, Au, etc. ⁵⁰. This behavior was explained in 1959 by Lifshits and Peschanskii ⁵¹, who took into account the shape of the Fermi surface and the anisotropy of MR. When averaged over all directions ($\Delta\theta \sim H_0/H$) and open sections of the Fermi surface (where $\rho \sim H^2$) for polycrystals, the MR acquires a linear dependence on the magnetic field ⁵¹. The open topology of the Fermi surface is confirmed by DFT calculations (Supporting Figures S11-S12).

7. Eliashberg functions

Calculations of the anharmonic correction to the critical temperature of superconductivity in this work are based on the constant DOS approximation ⁵², which is applicable if the density of electronic states N(E) in the vicinity of the Fermi energy has no pronounced features (e.g., van Hove singularities ⁵³) and can be approximately represented as a constant. In this case, the main contribution to the shape of Eliashberg function is made by the phonon density of states (denoted here for convenience as $F(\omega)$), and an auxiliary function of electron contribution $\alpha^2(\omega) = \alpha^2 F(\omega)/F(\omega)$ is close to a constant. The exceptions are those frequency zones where both functions $\alpha^2 F(\omega)$ and $F(\omega) \sim 0$, and where the calculation of their ratio is not sufficiently stable and accurate.

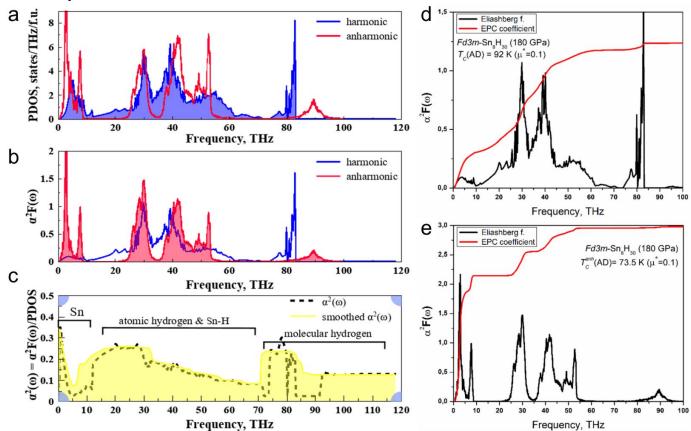


Figure S22. Harmonic and anharmonic spectral functions of $Fd\bar{3}m$ -Sn₈H₃₀ at 180 GPa, f.u. = Sn₈H₃₀. (a) Harmonic (blue) and anharmonic (red) density of phonon states at 100 K. (b) Harmonic (blue) and anharmonic (red) Eliashberg functions. (c) Smoothed (yellow) and original (black dotted line) function of contribution of the density of electronic states (formally, $\alpha^2(\omega)$). (d) Superconducting state parameters of $Fd\bar{3}m$ -Sn₈H₃₀ at 180 GPa in harmonic (d) and anharmonic (e) approximations. Attention is drawn to the presence of high-intensity soft modes in molecular dynamics calculations of Sn₈H₃₀ which can lead to the emergence of the charge density waves (CDW).

In this work, the procedure for calculating the Eliashberg anharmonic functions of Sn hydrides consisted of several steps:

- 1. Calculation of the harmonic Eliashberg function and phonon density of states in Quantum ESPRESSO ^{17,18} using the tetrahedral method ⁵⁴.
- 2. Calculation of the anharmonic phonon spectrum using the molecular dynamics 55 at a temperature near the superconducting transition ($T_{\rm C}$). Here it is a temperature of 100 K.
 - 3. Equalization of unit cell (N is number of atoms in the formula unit) by calibration of integrals

$$\int F_{harm}(\omega)d\omega = \int F_{anh}(\omega)d\omega = 3N$$
 (S8)

4. Calculation of the contribution of the electron density of states to the Eliashberg function for the harmonic case: $\alpha^2(\omega) = \alpha^2 F(\omega)/F(\omega)$.

- 5. Reduction of the function $\alpha^2(\omega) \ge 0$ to the same mesh on the energy scale that was used to calculate the anharmonic phonon spectrum by linear interpolation. All obtained negative values $\alpha^2(\omega) < 0$ were set to zero.
- 6. Smoothing the obtained $\alpha^2(\omega)$ to eliminate the influence of "empty" frequency zones where both $\alpha^2 F(\omega)$ and $F(\omega) \sim 0$. In this work, we used the percentile filter (points of window is 140, percentile is 70) in the OriginLab 2017 ⁵⁶ program.
- 7. Calculation of the Eliashberg anharmonic function as the product of the electronic contribution and the anharmonic density of phonon states $\alpha^2(\omega)F_{anh}(\omega)$.

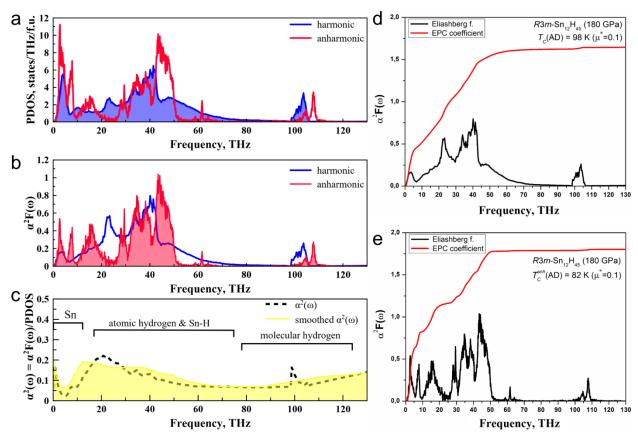


Figure S23. Harmonic and anharmonic spectral functions of $R\overline{3}m$ -Sn₁₂H₄₅ at 180 GPa, f.u. = Sn₁₂H₄₅. (a) Harmonic (blue) and anharmonic (red) density of phonon states at 100 K. (b) Harmonic (blue) and anharmonic (red) Eliashberg functions. (c) Smoothed (yellow) and original (black dotted line) function of contribution of the density of electronic states (formally, $\alpha^2(\omega)$). (d) Superconducting state parameters of $R\overline{3}m$ -Sn₁₂H₄₅ at 180 GPa in harmonic (d) and anharmonic (e) approximations.

Some details of the obtained results require discussion. First, the significant growth of the electron-phonon coupling (EPC) coefficient λ from 1.24 to \approx 3 in the anharmonic approximation attracts attention. The opposite effect is usually observed, which is associated with acoustic phonons hardening ⁵⁷. However, in our case, within the harmonic approximation, Sn_8H_{30} is not dynamically stable at 180-200 GPa, and has a series of imaginary acoustic modes that we did not take into account in our calculations of the superconducting state (see Figure S14). Considering anharmonic corrections, these imaginary modes, roughly speaking, move to the real acoustic part of the phonon spectrum, and cause a sharp maximum in $F(\omega)$ around 0-7 THz (Figure S15, S22), as well as lead to an increase in the EPC coefficient.

The intermediate range of frequencies, that corresponds to the atomic hydrogen vibrations (10-60 THz), is subjected to the aforementioned phonons hardening. As a result, the 10-25 THz frequency zone becomes almost empty, and the modes, that were previously in this region, cause a significant increase in the intensity of the $\alpha^2 F(\omega)$ and $F(\omega)$ functions in the range 25-55 THz (Figures S22a, b).

In the range of molecular hydrogen vibrations, anharmonic interactions of H₂ molecules with the framework of the atomic H-sublattice and with Sn atoms lead to the splitting and smoothing of the phonon

density of states in the range of 75-95 THz (Figure S22a, b). There is also a strong high-frequency shift of these modes, which is characteristic of the anharmonic approximation (for example, H₃S ⁵⁸, high-frequency region).

Thus, despite the pronounced phonons hardening for hydrogen modes, the effect of soft modes of Sn atoms (compare with hcp-NdH₉ ⁵⁹) leads to an unexpected increase in the electron-phonon interaction strength by more than two times and a sharp decrease in the logarithmically averaged frequency (ω_{log}) of Sn₈H₃₀ at 180 GPa. As a result, the critical temperature (T_C) is reduced by about 20 K compared to harmonic calculations, which is in qualitative agreement with the results obtained for other hydrides (e.g. AlH₃ ⁶⁰, YH₆ ^{16,61}, LaH₁₀ ^{62,63}, H₃S ⁴⁴).

Summing up, we can say that the properties of cubic SnH_4 are unusual: this compound exhibits much higher electron-phonon interaction strength ($\lambda = 2.5 - 3$) than one would expect from a hydride with such a low hydrogen content. SnH_4 can rather be described as a covalent superconductor, unlike lanthanum (LaH_{10}) and yttrium (YH_6) superhydrides.

Table S14. Superconducting properties of $Fd\overline{3}m$ -Sn₈H₃₀ at 180 GPa. AD – corresponds to calculations made by Allen-Dynes formula ²⁰. Calculations of elastic properties give the following estimates: $T_{\theta} = 380$ K, $\omega_{\log} \approx 315$ K (see below).

Parameter	λ	ω _{log} , K	ω2, Κ	$T_{\rm C}({\rm AD}), {\rm K}~(\mu^*=0.1)$
Harmonic*	1.24	892	1664	92.3
Anharmonic	2.98	282	1016	73.5

^{*}Coherence length in this case is about 5 nm, the Ginzburg-Landau parameter is $\kappa = 43$, and the expected lower critical field is $H_{C1} = 9$ mT.

Table S15. Superconducting properties of C2/m-SnH₁₄ at 200 GPa. AD – corresponds to calculations made by Allen-Dynes formula ²⁰. Calculations of elastic properties give the following estimates: $T_{\theta} = 1404 \text{ K}$, $\omega_{\log} \approx 1160 \text{ K}$ (see below).

Parameter	k-mesh	q-mesh	λ	ω _{log} , K	ω2, Κ	$T_{\rm C}({ m AD})$, K ($\mu^*=0.15$ -0.1)
Harmonic	12×12×12	2×2×2	1.27	1252	1930	107-133
Anharmonic	16×16×8	2×4×4	1.49	862	1585	93-112

Table S16. Critical temperatures of superconductivity for various tin polyhydrides predicted in previous years. It can be concluded that, despite the incorrect structures, the theoretical estimates of $T_{\rm C}$ are not very far from the experimental $T_{\rm C}({\rm SnH_4})$.

Phase	Pressure, GPa	$T_{\rm C}$, K	Consistency (±20 %) with	Reference
			the experimental $T_{ m C}$	
Ama2-SnH ₄	200	15-22	No	G. Gao et al. 38
$P6_3/mmc$ -SnH ₄	200	52-62	No	G. Gao et al 38
I4/mmm-SnH ₄	220	80-91	Yes	M. Davari et al. ³⁷
I4m2-SnH ₈	220	72-81	Yes	M. Davari et al. ³⁷

8. Elastic properties

The elastic constants of tin hydrides were evaluated using VASP code (with IBRION=6, ISIF=4) ¹⁰⁻¹². The kinetic energy cutoff for plane waves was 600 eV. Tetrahedron method with Blöchl corrections was used ⁶⁴. The purpose of the performed calculations is to get an estimate for the Debye temperature, and to confirm the conclusions about the "softness" of Sn₈H₃₀ obtained earlier on the basis of experimental data.

Table S17. Elastic properties of tin hydrides in harmonic approximation: $Fd\overline{3}m$ -Sn₈H₃₀ and C2/m-SnH₁₄.

Compound	C ₁₁ -C ₁₂ , GPa	C ₁₁ +2C ₁₂ , GPa	C ₄₄ , GPa	B, GPa	G, GPa	E, GPa	Poisson's ratio
Sn ₈ H ₃₀ (180 GPa)	179.1	1257.3	20.8	467.9	33.3*	97.5*	0.46
SnH ₁₄ (200 GPa)	409.5	1067.1	190.6	408.9	196.4	507.6	0.29

^{*} Rather low values for a pressure of 200 GPa, characterizing unusual "softness" of this hydride.

Table S18. Elastic tensor C_{ij} (in kbar) of $Fd\overline{3}m$ -Sn₈H₃₀ at 180 GPa in harmonic approximation. The Debye temperature is 380 K ⁶⁵.

	C _{i1}	C _{i2}	C _{i3}	C _{i4}	C _{i5}	C _{i6}
C_{1j}	5385.0973	3593.9683	4998.1048	19.781	53.2054	-67.0337
C_{2j}	3593.9683	6194.2358	4768.1404	19.276	-218.8843	4.2065
C_{3j}	4998.1048	4768.1404	3706.2409	91.0908	169.6859	328.4853
C_{4j}	19.781	19.276	91.0908	207.8296	59.2744	134.4097
C_{5j}	53.2054	-218.8843	169.6859	59.2744	496.8327	-14.6745
C _{6j}	-67.0337	4.2065	328.4853	134.4097	-14.6745	222.0507

Table S19. Elastic tensor C_{ij} (in kbar) of C2/m-SnH₁₄ at 200 GPa in harmonic approximation. The Debye temperature is 1404 K ⁶⁵.

	C _{i1}	C_{i2}	C _{i3}	C _{i4}	C _{i5}	C _{i6}
C_{1j}	6286.7031	2192.0071	3813.1104	0.0	0.0	-71.3417
C_{2j}	2192.0071	8677.1942	1284.712	0.0	0.0	384.5683
C _{3j}	3813.1104	1284.712	7304.6125	0.0	0.0	117.3508
C _{4j}	0.0	0.0	0.0	1906.2537	-357.1259	0.0
C _{5j}	0.0	0.0	0.0	-357.1259	1359.3217	0.0
C _{6j}	-71.3417	384.5683	117.3508	0.0	0.0	2313.0626

References

- Oganov, A. R., Glass, C. W. Crystal structure prediction using ab initio evolutionary techniques: Principles and applications. *J. Chem. Phys.* **124**, 244704 (2006).
- Oganov, A. R., Lyakhov, R. O., Valle, M. How Evolutionary Crystal Structure Prediction Works-and Why. *Acc. Chem. Res.* **44**, 227-237 (2011).
- 3 Lyakhov, A. O., Oganov, A. R., Stokes, H. T. *et al.* New developments in evolutionary structure prediction algorithm USPEX. *Comput. Phys. Commun.* **184**, 1172-1182 (2013).
- Bushlanov, P. V., Blatov, V. A., Oganov, A. R. Topology-based crystal structure generator. *Comput. Phys. Commun.* **236**, 1-7 (2019).
- 5 Hohenberg, P., Kohn, W. Inhomogeneous Electron Gas. *Phys. Rev.* **136**, B864-B871 (1964).
- 6 Kohn, W., Sham, L. J. Self-Consistent Equations Including Exchange and Correlation Effects. *Phys. Rev.* **140**, A1133-A1138 (1965).
- Perdew, J. P., Burke, K., Ernzerhof, M. Generalized Gradient Approximation Made Simple. *Phys. Rev. Lett.* **77**, 3865-3868 (1996).
- 8 Kresse, G., Joubert, D. From ultrasoft pseudopotentials to the projector augmented-wave method. *Phys. Rev. B* **59**, 1758-1775 (1999).
- 9 Blöchl, P. E. Projector augmented-wave method. *Phys. Rev. B* **50**, 17953-17979 (1994).
- 10 Kresse, G., Furthmüller, J. Efficient iterative schemes for ab initio total-energy calculations using a plane-wave basis set. *Phys. Rev. B* **54**, 11169 (1996).
- Kresse, G., Hafner, J. Ab initiomolecular-dynamics simulation of the liquid-metal–amorphous-semiconductor transition in germanium. *Phys. Rev. B* **49**, 14251-14269 (1994).
- Kresse, G., Hafner, J. Ab initio molecular dynamics for liquid metals. *Phys. Rev. B* 47, 558-561 (1993).
- Togo, A., Tanaka, I. First principles phonon calculations in materials science. *Scr. Mater.* **108**, 1-5 (2015).
- Togo, A., Oba, F., Tanaka, I. First-principles calculations of the ferroelastic transition between rutile-type and CaCl₂-typeSiO₂ at high pressures. *Phys. Rev. B* **78**, 134106 (2008).
- Semenok, D. V., Troyan, I. A., Kvashnin, A. G. *et al.* Superconductivity at 253 K in lanthanum-yttrium ternary hydrides. *Mater. Today* **48**, 18-28 (2021).
- Troyan, I. A., Semenok, D. V., Kvashnin, A. G. *et al.* Anomalous High Temperature Superconductivity in YH₆. *Adv. Mater.* **33**, 2006832 (2021).
- Giannozzi, P., Baroni, S., Bonini, N. *et al.* QUANTUM ESPRESSO: a modular and open-source software project for quantum simulations of materials. *J. Phys.: Condens. Matter* **21**, 395502 (2009).
- Giannozzi, P., Andreussi, O., Brumme, T. *et al.* Advanced capabilities for materials modelling with Quantum ESPRESSO. *J. Phys.: Condens. Matter* **29**, 465901 (2017).
- Baroni, S., Gironcoli, S. d., Corso, A. D. *et al.* Phonons and related crystal properties from density-functional perturbation theory. *Rev. Mod. Phys.* **73**, 515-562 (2001).
- Allen, P. B., Dynes, R. C. Transition temperature of strong-coupled superconductors reanalyzed. *Phys. Rev. B* **12**, 905-922 (1975).
- 21 Shapeev, A. V. Moment Tensor Potentials: A Class of Systematically Improvable Interatomic Potentials. *Multiscale Model. Simul.* **14**, 1153-1173 (2016).
- Ladygin, V. V., Korotaev, P. Y., Yanilkin, A. V. *et al.* Lattice dynamics simulation using machine learning interatomic potentials. *Comput. Mater. Sci.* **172**, 109333 (2020).
- Podryabinkin, E. V., Shapeev, A. V. Active learning of linearly parametrized interatomic potentials. *Comput. Mater. Sci.* **140**, 171-180 (2017).
- Dickey, J. M., Paskin, A. Computer Simulation of the Lattice Dynamics of Solids. *Phys. Rev.* **188**, 1407-1418 (1969).
- Appel, J. Atomic ordering and *Tc* of narrow-band superconducting alloys. *Phys. Rev B* **13**, 3203-3208 (1976).
- Talantsev, E., Crump, W. P., Tallon, J. L. Thermodynamic Parameters of Single- or Multi-Band Superconductors Derived from Self-Field Critical Currents. *Annalen der Physik* **529**, 1700197 (2017).
- Talantsev, E. F., Tallon, J. L. Universal self-field critical current for thin-film superconductors. *Nat. Commun.* **6**, 7820 (2015).

- Laniel, D., Trybel, F., Winkler, B. *et al.* High-pressure synthesis of seven lanthanum hydrides with a significant variability of hydrogen content. *Nat. Commun.* **13**, 6987 (2022).
- Aslandukov, A., Aslandukov, M., Dubrovinskaia, N. *et al.* Domain Auto Finder (DAFi) program: the analysis of single-crystal X-ray diffraction data from polycrystalline samples. *J appl. crystallogr.* **55**, 1383-1391 (2022).
- Laniel, D., Winkler, B., Bykova, E. *et al.* Novel sulfur hydrides synthesized at extreme conditions. *Phys. Rev. B* **102** (2020).
- Prescher, C., Prakapenka, V. B. DIOPTAS: a program for reduction of two-dimensional X-ray diffraction data and data exploration. *High Pressure Res.* **35**, 223-230 (2015).
- Petříček, V., Dušek, M., Palatinus, L. Crystallographic Computing System JANA2006: General features. *Z. Kristallogr.* **229**, 345-352 (2014).
- Le-Bail, A. Whole powder pattern decomposition methods and applications: A retrospection. *Powder Diffraction* **20**, 316-326 (2005).
- Eremets, M. I. Megabar high-pressure cells for Raman measurements. *J. Raman Spectrosc.* **34**, 515-518 (2003).
- Mitamura, H., Watanuki, R., Kampert, E. *et al.* Improved accuracy in high-frequency AC transport measurements in pulsed high magnetic fields. *Review of Scientific Instruments* **91**, 125107 (2020).
- Semenok, D. V., Troyan, I. A., Sadakov, A. V. *et al.* Effect of Magnetic Impurities on Superconductivity in LaH₁₀. *Adv. Mater.* **34**, 2204038 (2022).
- Esfahani, M. M. D., Wang, Z., Oganov, A. R. *et al.* Superconductivity of novel tin hydrides (Sn(n)H(m)) under pressure. *Sci. Rep.* **6**, 22873 (2016).
- Gao, G., Oganov, A. R., Li, P. *et al.* High-pressure crystal structures and superconductivity of Stannane (SnH₄). *Proc. Natl. Acad. Sci. U S A* **107**, 1317-1320 (2010).
- 39 Glass, C. W., Oganov, A. R., Hansen, N. USPEX—Evolutionary crystal structure prediction. *Comput. Phys. Commun.* **175**, 713-720 (2006).
- Bykov, M., Chariton, S., Fei, H. *et al.* High-pressure synthesis of ultraincompressible hard rhenium nitride pernitride Re₂(N₂)(N)₂ stable at ambient conditions. *Nat. Commun.* **10**, 2994 (2019).
- Semenok, D. Computational design of new superconducting materials and their targeted experimental synthesis Doctoral program in matraials science and engineering thesis, Skoltech, (2022).
- 42 Chen, W., Huang, X., Semenok, D. V. *et al.* Enhancement of superconducting critical temperature realized in La-Ce-H system at moderate pressures. *arXiv*:2203.14353 (2022).
- Sun, D., Minkov, V. S., Mozaffari, S. *et al.* High-temperature superconductivity on the verge of a structural instability in lanthanum superhydride. *Nat. Commun.* **12**, 6863 (2021).
- Drozdov, A. P., Eremets, M. I., Troyan, I. A. *et al.* Conventional superconductivity at 203 kelvin at high pressures in the sulfur hydride system. *Nature* **525**, 73-76 (2015).
- Chen, W., Semenok, D. V., Kvashnin, A. G. *et al.* Synthesis of molecular metallic barium superhydride: pseudocubic BaH₁₂. *Nat. Commun.* **12**, 273 (2021).
- Chen, W., Semenok, D. V., Huang, X. *et al.* High-Temperature Superconducting Phases in Cerium Superhydride with a *Tc* up to 115 K below a Pressure of 1 Megabar. *Phys. Rev. Lett.* **127**, 117001 (2021).
- Bloch, F. Zum elektrischen Widerstandsgesetz bei tiefen Temperaturen. Z. Physik **59**, 208-214 (1930).
- 48 Grüneisen, E. Die Abhängigkeit des elektrischen Widerstandes reiner Metalle von der Temperatur. *Ann. Phys.* **408**, 530-540 (1933).
- Mustafa, J. I., Bernardi, M., Neaton, J. B. *et al.* Ab initio electronic relaxation times and transport in noble metals. *Phys. Rev. B* **94**, 155105 (2016).
- Kapitza, P., Rutherford, E. The change of electrical conductivity in strong magnetic fields. Part I. Experimental results. *Proc. R. Soc. Lond. A* **123**, 292-341 (1929).
- Lifshitz, I. M., Peschanskii, V. G. Galvanomagnetic characteristics of metals with open Fermi surfaces. *Sov. Phys. JETP* **8**, 875 (1959).
- Sano, W., Koretsune, T., Tadano, T. *et al.* Effect of Van Hove singularities on high-Tcsuperconductivity in H₃S. *Phys. Rev. B* **93**, 094525 (2016).
- Van Hove, L. The Occurrence of Singularities in the Elastic Frequency Distribution of a Crystal. *Phys. Rev.* **89**, 1189-1193 (1953).

- Kawamura, M., Gohda, Y., Tsuneyuki, S. Improved tetrahedron method for the Brillouin-zone integration applicable to response functions. *Phys. Rev. B* **89**, 094515 (2014).
- Errea, I., Calandra, M., Mauri, F. Anharmonic free energies and phonon dispersions from the stochastic self-consistent harmonic approximation: Application to platinum and palladium hydrides. *Phys. Rev. B* **89**, 064302 (2014).
- Edwards, P. M. Origin 7.0: Scientific Graphing and Data Analysis Software. *J. Chem. Inf. Model.* **42**, 1270-1271 (2002).
- Errea, I., Belli, F., Monacelli, L. *et al.* Quantum crystal structure in the 250-kelvin superconducting lanthanum hydride. *Nature* **578**, 66-69 (2020).
- Errea, I., Calandra, M., Pickard, C. J. *et al.* Quantum hydrogen-bond symmetrization in the superconducting hydrogen sulfide system. *Nature* **532**, 81-84 (2016).
- Zhou, D., Semenok, D. V., Xie, H. et al. High-Pressure Synthesis of Magnetic Neodymium Polyhydrides. J. Am. Chem. Soc. 142, 2803–2811 (2020).
- Hou, P., Belli, F., Bianco, R. *et al.* Strong anharmonic and quantum effects in Pm-3n AlH₃ under high pressure: A first-principles study. *Phys. Rev. B* **103**, 134305 (2021).
- Kong, P., Minkov, V. S., Kuzovnikov, M. A. *et al.* Superconductivity up to 243 K in the yttrium-hydrogen system under high pressure. *Nat. Commun.* **12**, 5075 (2021).
- Drozdov, A. P., Kong, P. P., Minkov, V. S. *et al.* Superconductivity at 250 K in lanthanum hydride under high pressures. *Nature* **569**, 528-531 (2019).
- 63 Somayazulu, M., Ahart, M., Mishra, A. K. *et al.* Evidence for Superconductivity above 260 K in Lanthanum Superhydride at Megabar Pressures. *Phys. Rev. Lett.* **122**, 027001 (2019).
- Blöchl, P. E., Jepsen, O., Andersen, O. K. Improved tetrahedron method for Brillouin-zone integrations. *Phys. Rev. B* **49**, 16223-16233 (1994).
- Ravindran, P., Fast, L., Korzhavyi, P. A. *et al.* Density functional theory for calculation of elastic properties of orthorhombic crystals: Application to TiSi₂. *J. Appl. Phys.* **84**, 4891-4904 (1998).